° ICOM

SERVICE MANUAL

VHF MARINE TRANSCEIVER

Icom Inc.

INTRODUCTION

This service manual describes the latest service information for the IC-M7 VHF MARINE TRANSCEIVER at the time of going to press.

8 versions of the IC-M7 have been designed. This service manual covers each version.

VERSION NUMBER	VERSION	MODEL
#01	U.S.A.	USA
#02	France	FRA
#03	U.K.	UK
#04	Holland	HOL
#05	Australia	AUS
#06	General-1	GEN1
#07	General-2	GEN2
#08	Europe	EUR
#09	Italy	ITA

To upgrade quality, any electric or mechanical part and internal circuits are subject to change without notice or obligation.

DANGER

NEVER connect the transceiver to an AC outlet or to a DC power supply that uses more than 16 V. This will ruin the transceiver.

DO NOT expose the transceiver to rain, snow or any liquids.

DO NOT reverse the polarities of the power supply when connecting the transceiver.

DO NOT apply an RF signal of more than 20 dBm (100 mW) to the antenna connector. This could damage the transceiver's front end.

ORDERING PARTS

Be sure to include the following four points when ordering replacement parts:

- 1. 10-digit order numbers
- 2. Component part number and name
- 3. Equipment model name and unit name
- 4. Quantity required



<SAMPLE ORDER>

1150000780	IC	SC1106	IC-M7	MAIN UNIT	5 pieces
8810005720	Screw	PH B0 M2 × 20 ZK	IC-M7	Rear panel	10 pieces

Addresses are provided on the inside back cover for your convenience.

REPAIR NOTE

- 1. Make sure a problem is internal before disassembling the transceiver.
- DO NOT open the transceiver until the transceiver is disconnected from a power source.
- DO NOT force any of the variable components. Turn them slowly and smoothly.
- DO NOT short any circuits or electronic parts. An insulated tuning tool MUST be used for all adjustments.
- 5. DO NOT keep power ON for a long time when the transceiver is defective.
- 6. DO NOT transmit power into a signal generator or a sweep generator.
- ALWAYS connect a 30 dB~40 dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- READ the instructions of test equipment thoroughly before connecting equipment to the transceiver.

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SECTION 1 SPECIFICATIONS

GENERAL

 Frequency range 	:	VERSION	USA	FBA	UK	HOL	AUS	GEN1	GEN2	EUR	ITA
		International Channels	•	•	•	*	•	•	•	•	•
		U.S.A. Channels	•	—	٠		•	•	•	—	•
		Weather Channels	•				•	٠	•		
						•: Yes	-: 1	No *:	Holland	channel	s only
 Type of emission 	:	FM (16K0G3E)									
 Frequency stability 	:	±0.0005 %									
 Antenna impedance 	:	50 Ω unbalanced	t								
 Power supply requirement 	;	Icom battery cas	com battery packs BP-81 \sim BP-85 and CM-89 com battery case (AA (R6) size dry batteries or NiCd batteries \times 6) BP-90 Negative ground)								
 Usable temperature range 	;	-20 °C~+60 °C	C(−4 °I	+14	0 °F)						
Dimensions	:	1.9 (W) × 4.8 (H) 103.5 (H) mm; 4	49 (W) × 123 (H) × 33 (D) mm 1.9 (W) × 4.8 (H) × 1.3 (D) in (with CM-89) 103.5 (H) mm; 4.1 (H) in (with BP-82) (Projections not included)								
 Weight 	:	310 g; 10.9 oz (v 278 g; 9.8 oz (w									

TRANSMITTER

 RF output power 	:	High: 5.0 W (FRA version 1.0 W)
(at 12.5 V DC)		Low : 500 mW (FRA version 150 mW)
 Modulation system 	:	Variable reactance frequency modulation
Current drain (at 12.5 V DC)	:	High power 1.8 A (FRA version 1.0 A)
		Low power 0.9 A (FRA version 0.5 A)
 Microphone impedance 	:	2 kΩ
 Maximum deviation 	:	±5 kHz
 Spurious emissions 	:	-65 dB
 FM hum and noise 	:	-40 dB
 Audio response 	:	+1 dB \sim -3 dB of +6 dB/octave from 300 Hz to 3000 Hz

RECEIVER

 Receive system 	:	Double-conversion superheterodyne
 Sensitivity 	:	0.35 µV for 12 dB SINAD
Squelch threshold sensitivity	:	0.32 μV
 Intermediate frequencies 	:	1st 30.875 MHz 2nd 455 kHz
Current drain (at 12.5 V DC)	:	Audio max. 300 mA Power saved 15 mA
 Audio output power 	:	500 mW
 Audio output impedance 	:	8 Ω
 Adjacent selectivity 	:	-60 dB
 Spurious frequency rejection 	:	-60 dB
 Intermodulation 	:	60 dB
 Noise and hum 	:	-40 dB
 Audio response 	:	+1 dB \sim -3 dB of -6 dB/octave from 300 Hz to 3000 Hz

All stated specifications are subject to change without notice or obligation.

WHF MARINE TRANSCEIVER CHANNEL CHART

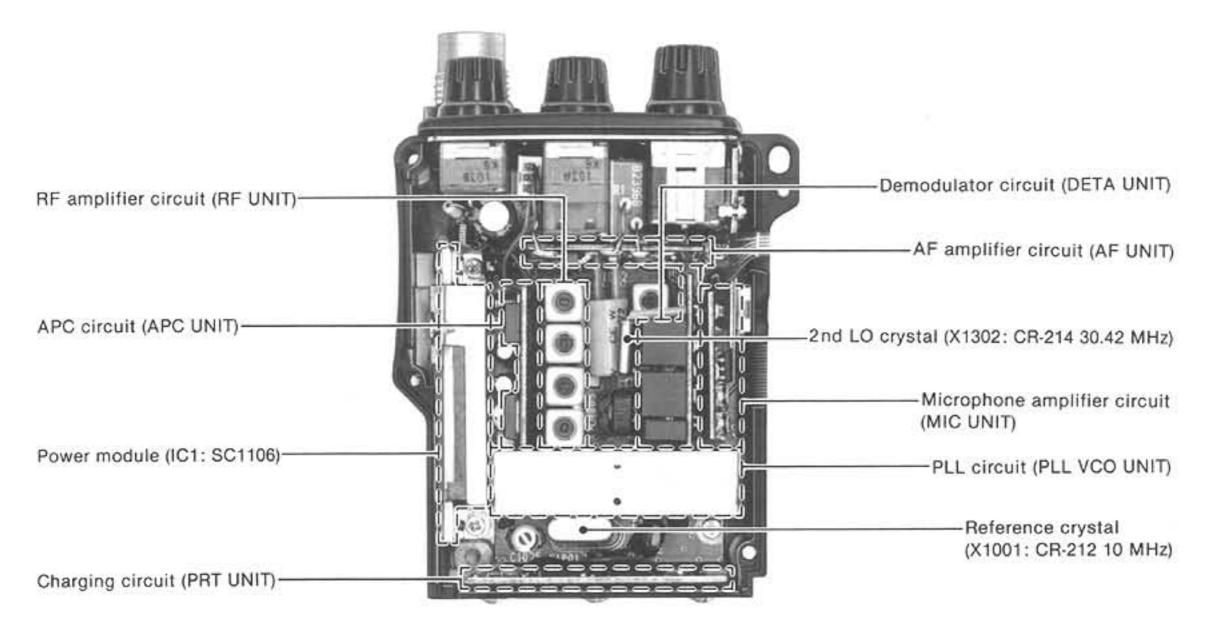
Channel number		Frequen	Ch	annel num	ber	Frequency (MHz)			
INT 1	INT 2	USA	Transmitter	Receiver	INT 1	INT 2	USA	Transmitter	Receiver
01	01		156.050	160.650	62	62		156.125	160.725
	01A	01A	156.050	156.050		62A	62A	156,125	156.125
02	02		156.100	160.700	63	63		156.175	160.775
	02A	02A	156.100	156.100		63A	63A	156.175	156.175
03	03		156.150	160.750	64	64		156.225	160.825
	03A	03A	156.150	156.150		64A	64A	156.225	156.225
04	04		156.200	160.800	65	65		156.275	160.875
	04A	04A	156.200	156.200		65A	65A	156.275	156.275
05	05		156.250	160.850	66	66		156.325	160.925
	05A	05A	156.250	156.250		66A	66A	156.325	156.325
06	06	06	156.300	156.300	67	67	67	156.375	156.375
07	07		156.350	160.950	68	68	68	156.425	156.425
	07A	07A	156.350	156.350	69	69	69	156.475	156.475
08	08	08	156.400	156.400	70	70	70	156.525	156.525
09	09	09	156.450	156.450	71	71	71	156.575	156.575
10	10	10	156.500	156.500	72	72	72	156.625	156.625
11	11	11	156.550	156.550	73	73	73	156.675	156.675
12	12	12	156.600	156.600	74	74	74	156.725	156.725
13	13	13	156.650	156.650	75	75	75	Guard	Guard
14	14	14	156.700	156.700	76	76	76	Guard	Guard
15	15	15*	156.750	156.750	77	77	77	156.875	156.875
16	16	16	156.800	156.800	78	78		156.925	161.525
17	17	17	156.850	156.850		78A	78A	156.925	156.925
18	18		156.900	161.500	79	79		156.975	161.575
	18A	18A	156.900	156.900		79A	79A	156.975	156.975
19	19		156.950	161.550	80	80		157.025	161.625
	19A	19A	156.950	156.950		80A	80A	157.025	157.025
20	20	20	157.000	161.600	81	81		157.075	161.675
	20A	20A	157.000	157.000	1	81A	81A	157.075	157.075
21	21		157.050	161.650	82	82		157.125	161.725
	21A	21A	157.050	157.050		82A	82A	157.125	157.125
22	22		157.100	161.700	83	83		157.175	161.775
	22A	22A	157.100	157.100		83A	83A	157.175	157.175
23	23		157.150	161.750	84	84	84	157.225	161.825
	23A	23A	157.150	157.150		84A		157.225	157.225
24	24	24	157.200	161.800	85	85	85	157.275	161.875
25	25	25	157.250	161.850		85A		157.275	157.275
26	26	26	157.300	161.900	86	86	86	157.325	161.925
27	27	27	157.350	161.950		86A	86A	157.325	157.325
28	28	28	157.400	162.000	87	87	87	157.375	161.975
60	60		156.025	160.625		87A		157.375	157.375
	60A	60A	156.025	156.025	88	88	88	157.425	162.025
61	61		156.075	160.675		88A	88A	157.425	157.425
	61A	61A	156.075	156.075					

WV ob on the	Frequenc	cy (MHz)	WV shared	Frequency (MI Transmitter RX only RX only RX only RX only RX only RX only	cy (MHz)
WX channel	Transmitter	Receiver	WX channel	Transmitter	Receiver
WX 01	RX only	162.550	WX 06	RX only	162.500
WX 02	RX only	162.400	WX 07	RX only	162.525
WX 03	RX only	162.475	WX 08	RX only	161.650
WX 04	RX only	162.425	WX 09	RX only	161.775
WX 05	RX only	162.450	WX 10	RX only	163.275

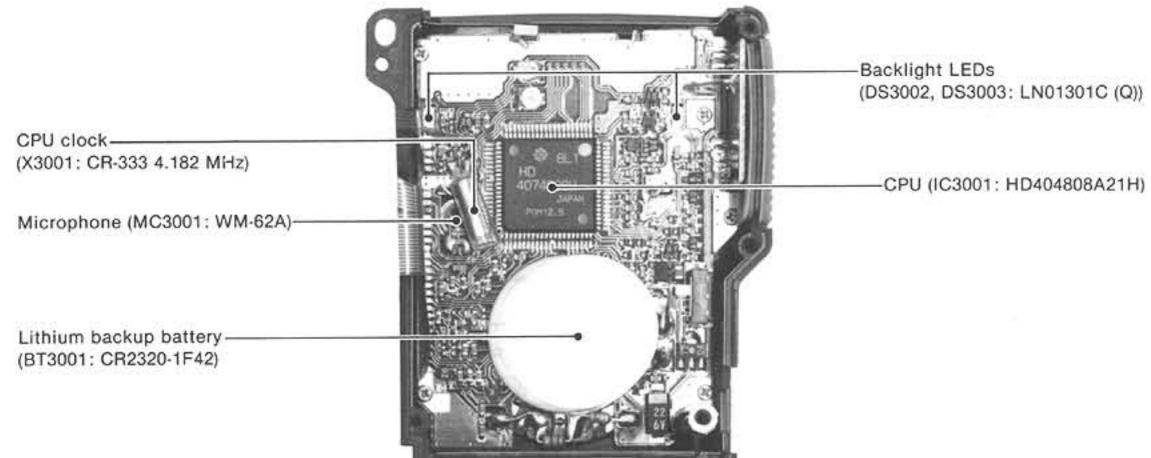
* U.S.A. channel 15 is a receive-only channel.

SECTION 2 **INSIDE VIEWS**

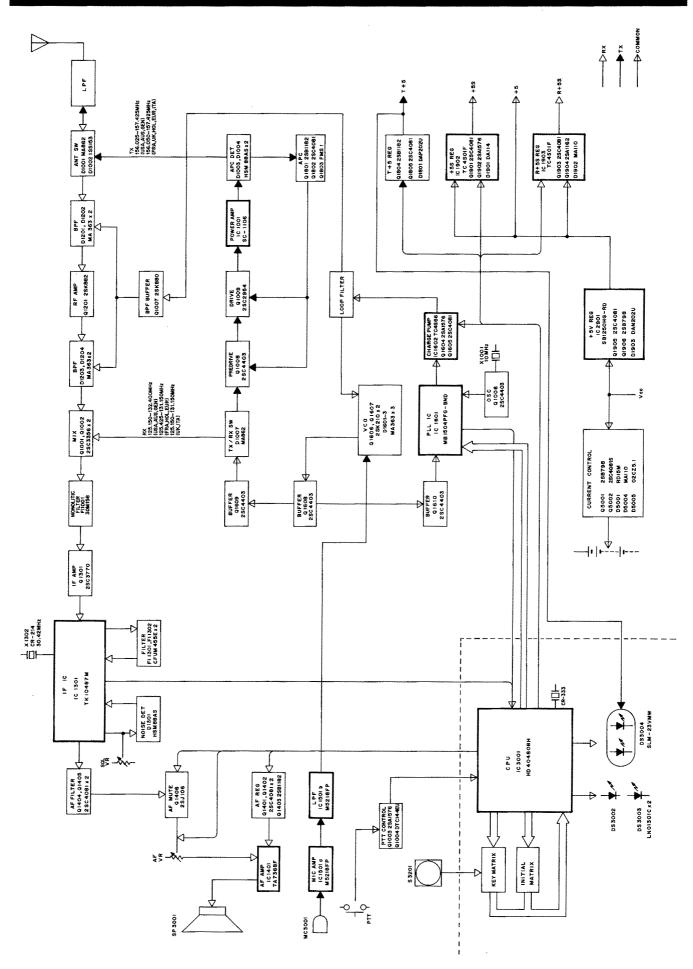
MAIN UNIT



LOGIC UNIT



SECTION 3 BLOCK DIAGRAM



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4-1 RECEIVER CIRCUITS

4-1-1 ANTENNA SWITCHING CIRCUIT (MAIN UNIT)

An antenna switching circuit switches the transmit/receive circuit, it functions as a low-pass filter while receiving and as a resonator circuit while transmitting.

Received signals enter the antenna connector and pass through a low-pass filter (L1001, L1002, C1001 \sim C1005). The signals are applied to the antenna switching circuit (D1001, D1002, L1003, L1004, C1007 \sim C1009), and then to the RF circuit. The antenna switching circuit employs a λ /4-type diode switching system. The signals are applied to the RF UNIT via the RF IN signal line.

4-1-2 RF CIRCUIT (RF UNIT)

The RF circuit amplifies signals within the range of frequency coverage, and filters out out-of-band signals.

The signals from the antenna switching circuit pass through a bandpass filter (D1201, D1202, L1251, L1252, C1202 \sim C1204, C1214, C1215), and are applied to the RF amplifier (Q1201).

Amplified signals are reapplied to the other bandpass filter (D1203, D1204, L1253, L1254, C1207~C1210, C1216, C1217) to suppress unwanted signals. The signals are applied to a 1st mixer circuit (MAIN UNIT Q1001, Q1002).

D1201~D1204 are varactor diodes that track the bandpass filters and are controlled by the PLL lock voltage. These diodes tune the center frequency of the bandpass filters for wide bandwidth reception and good image response rejection.

4-1-3 1ST MIXER CIRCUIT (MAIN UNIT)

The 1st mixer circuit converts the received signal to a fixed frequency of 1st IF signal using a PLL output frequency. By changing a PLL frequency, only the desired frequency can be passed through a crystal filter located at the next stage of the 1st mixer.

The signals from the RF circuit are mixed with a 1st LO signal from the PLL UNIT to produce a 30.875 MHz 1st IF signal.

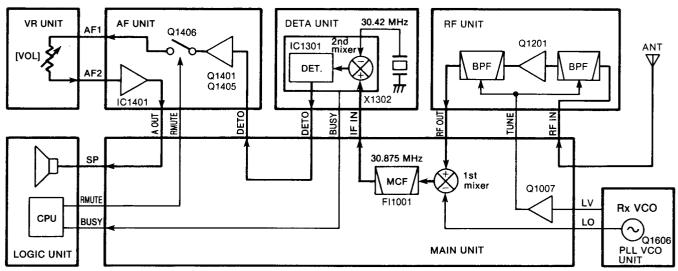
4-1-4 1ST IF CIRCUIT (MAIN AND DETA UNITS)

A 1st IF circuit amplifies a signal which is converted in the 1st mixer circuit.

After passing through the matching circuit (L1006), the 1st IF signal is applied to a pair of crystal filters (FI1001) to suppress out-of-band signals. The 1st IF signal enters the DETA UNIT and is amplified at an IF amplifier (Q1301) and then applied to a 2nd mixer circuit.

4-1-5 2ND IF AND DEMODULATOR CIRCUITS (DETA UNIT)

The 2nd mixer circuit converts the 1st IF signal to a 2nd IF signal. A double superheterodyne system (2 times conversion of a receive signal) improves the image rejection ratio and obtains stable receiver gain.



RECEIVER CIRCUIT BLOCK DIAGRAM

The 1st IF signal from Q1301 is applied to the 2nd mixer section of IC1301, and is mixed with a 2nd LO signal to be converted to a 455 kHz 2nd IF signal.

IC1301 contains the 2nd mixer, local oscillator, limiter amplifier and quadrature detector circuits. The local oscillator section and X1302 generate 30.420 MHz for the 2nd LO signal.

The 2nd IF signal from the 2nd mixer (IC1301, pin 4) passes through ceramic filters (FI1301, FI1302), where unwanted signals are suppressed. It is then amplified at the limiter amplifier section (IC1301, pin 6) and applied to the quadrature detector section (IC1301, pin 10 and ceramic discriminator X1301) to demodulate the 2nd IF signal into an AF signal.

AF signal output from IC1301 pin 11 is applied to a squelch circuit and de-emphasis circuit (R1312, C1318). This de-emphasis circuit is an integrated circuit with frequency characteristics of $-6 \, dB/octave$. The resulting signal is applied to the AF circuit.

FM DEMODULATOR CIRCUIT

Discrimi-855 nator X1301 455 kHz X1302 FI1301. 30.42 MHz FI1302 10 Limiter amp IC1301 FM TK10487M detector Sauelch 2nd trigger mixe Noise amp 20 13 15 16 11 14 1st IF 30.875 MHz De Noise DETO emphasis DET to AF amp BUSY to CPU Fig. 2

4-1-6 AF CIRCUIT (AF AND VR UNITS)

An AF circuit amplifies the signals to drive a speaker. The AF circuit includes a mute circuit to mute the signal with a noise squelch.

The AF signal is applied to Q1404 and Q1405 on the AF UNIT. Q1404 is an active filter that functions as a highpass filter to suppress unwanted low-frequency signals. Q1405 is also an active filter that functions as a low-pass filter to suppress higher noise signals.

The filtered signal is applied to the [VOL] control (R4001) on the VR UNIT via the AF mute circuit (Q1406). The AF signal is power-amplified at the AF power amplifier (IC1401) to drive the speaker.

The AF voltage regulator (Q1401 \sim Q1403) supplies power to the AF power amplifier. The AF ON signal from the CPU controls Q1401 and mutes AF output while receiving no signal.

4-1-7 SQUELCH CIRCUIT (DETA UNIT)

A squelch circuit cuts out AF signals when no RF signal is received. By detecting noise components in the AF signals, the squelch circuit switches the AF power amplifier.

Some of the noise components in the AF signal from IC1301 pin 11 are applied to IC1301 pin 13 via C1314, R1308, C1315 and C1311. The [SQL] control (R4002) on the VR UNIT adjusts the IC1301 pin 13 input level.

The active filter section in IC1301 amplifies noise components of frequencies of 20 kHz and above, and outputs the resulting signals from IC1301 pin 14. Output signals are rectified by D1301 and are converted to DC voltage.

The DC voltage triggers the squelch circuit in IC1301. IC1301 pin 16 outputs the squelch signal. The signal is applied to the CPU (IC3001, pin 27) on the LOGIC UNIT through the BUSY signal line. The CPU outputs the RMUTE and BUSY LED signals.

The RMUTE signal activates the AF mute circuit (Q1406) on the AF UNIT to cut the AF signal. The BUSY LED signal is applied to Q3003 on the LOGIC UNIT, turning OFF the receive indicator.

4-2 TRANSMITTER CIRCUITS

4-2-1 MICROPHONE AMPLIFIER (MIC UNIT)

The microphone amplifier circuit amplifies audio signals with +6 dB/octave pre-emphasis from the microphone to a level needed at the modulation circuit.

AF signals from the built-in condenser microphone or from the [MIC] jack are applied to IC1501 pin 3, and are preemphasized to $+6 \, \text{dB/octave}$ through C1506 and R1503 connected to pin 2. IC1501 functions as the microphone amplifier and the limiter.

The output signals from IC1501 pin 1 pass through the splatter filter circuit (IC1501 pins 5 and 6) where signals of 3 kHz and above are attenuated. IC1501 pin 7 then outputs the signals. The signals are applied to the modulation circuit (PLL VCO UNIT, D1603) in the VCO to produce an FM signal.

The VCO circuit (Q1607, D1602, D1603) on the PLL VCO UNIT oscillates the transmit frequency with AF signal modulation.

4-2-2 DRIVE AMPLIFIER (MAIN UNIT)

The drive amplifier circuit amplifies the VCO oscillating signal.

The VCO output, buffer-amplified at Q1609 on the PLL VCO UNIT, is applied to the the transmit/receive switching circuit (D1007) on the MAIN UNIT. The VCO output is then amplified at the predrive amplifier (Q1008) and the drive amplifier (Q1009).

The voltage controlled by the APC circuit is applied to the collector of Q1008 and Q1009 to protect the RF power module from damage by an antenna mismatch.

4-2-3 RF POWER AMPLIFIER (MAIN UNIT)

The power amplifier circuit amplifies the drive signal.

IC1001 is a power module which provides stable 5 W output power. (FRA version: 1 W) An RF signal from the drive amplifier (Q1009) is applied to IC1001 pin 1. The amplified signal is output from pin 4, and applied to the antenna connector through the diode switching and low-pass filter circuits.

4-2-4 APC CIRCUIT (MAIN AND APC UNITS)

The APC circuit protects the power module (IC1001) from a mismatched output load and selects HIGH and LOW output power.

The output power level from the power module (IC1001) is detected at the APC detector (D1003~D1005). When antenna impedance is matched at 50 Ω , the detected level is at a minimum. However, when antenna impedance is mismatched, the detected voltage is higher than when matched.

When the antenna impedance is mismatched, the base voltage of Q1803b (APC UNIT) is higher than the other base voltage of Q1803a (reference voltage). Q1803b decreases the collector current of Q1801 using Q1802. Collector current of Q1801 is used at the drive amplifiers (Q1008, Q1009) on the MAIN UNIT. Hence, when the antenna impedance is mismatched, the output power is decreased.

The output power selecting circuit uses the APC circuit. The [HI/LOW] switch selects the reference voltage, changing the output power to HIGH or LOW.

4-2-5 ANTENNA SWITCHING CIRCUIT (MAIN UNIT)

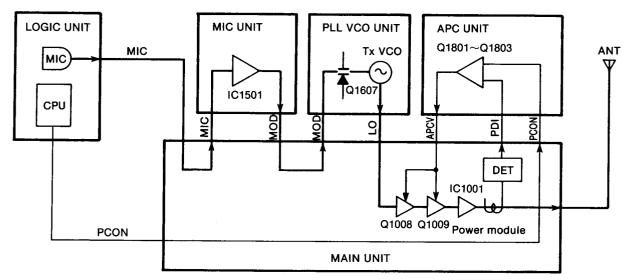
The antenna switching circuit applies the received signal to the receiver circuits and the transmitter signal to the antenna connector.

When transmitting, D1001 and D1002 are turned ON. The RF output signal is not applied to the receiver circuit, passing through D1002 and C1006, the low-pass filter (L1001, L1002, C1001 \sim C1005) and then to the antenna. The low-pass filter suppresses high harmonic components.

4-3 PLL CIRCUITS

4-3-1 GENERAL (PLL VCO UNIT)

A PLL circuit stably oscillates the transmit frequency and the receive local frequency. The PLL output frequency is controlled by the divided ratio (N-data) of the programmable divider.



TRANSMITTER CIRCUIT BLOCK DIAGRAM

Fig. 3

The PLL circuit, using a one chip modulus prescaler (IC1601), directly generates the transmit frequency with the Tx VCO (Q1607) and the 1st LO frequency with the Rx VCO (Q1606). The modulus prescaler (IC1601) sets the dividing ratio based on serial data from the CPU, and compares the phases of a VCO signal and the reference oscillator frequency. It detects the out-of-step phase and outputs it. The reference frequency is oscillated at X1001 on the MAIN UNIT.

4-3-2 REFERENCE OSCILLATOR CIRCUIT (MAIN UNIT)

A reference frequency is produced by the local oscillator (Q1006) and X1001. D1008 and R1029 provide frequency control. Thus, the output frequency of this circuit is stable over a wide temperature range.

4-3-3 LOOP FILTER CIRCUIT (PLL VCO UNIT)

Phase-detected signals from IC1601 pin 15 and 16 are converted to DC voltage by a charge pump (Q1604, Q1605) and lag-lead loop filter (R1606, R1607, C1605, C1606). The DC voltage is applied to varactor diodes (D1601 \sim D1603) in the VCO to lock the VCO oscillation.

On the other hand, the output of the loop filter passes though Q1007 on the MAIN UNIT and is used as the tuning voltage for the RX bandpass filters.

4-3-4 VCO CIRCUIT (PLL VCO UNIT)

The IC-M7 has 2 VCO circuits for transmitting and receiving which generate the receive and transmit frequencies and makes an FM modulation.

The CPU outputs a control signal for selecting the receive VCO circuit (Q1606, L1602, D1601) or transmit VCO circuit (Q1607, L1605, D1602, D1603). Varactor diodes (D1601 \sim D1603) provide frequency control. The buffer amplifiers (Q1608 \sim Q1610) do not affect the PLL output signal from VCO oscillation. Q1601 selects the transmit or receive VCO circuit.

4-3-5 UNLOCK SENSOR CIRCUIT (PLL VCO UNIT)

When the PLL circuit is unlocked, IC1601 pin 7 is "LOW" and a "LOW" signal is applied to Q1005 on the MAIN UNIT and then to the CPU pin 7 as an unlock signal.

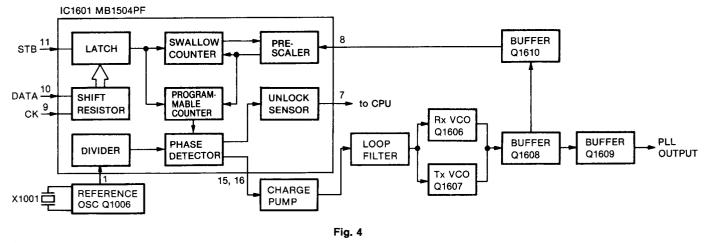
4-4 POWER SUPPLY CIRCUITS

4-4-1 VOLTAGE LINES

LINE	DESCRIPTION
Vcc	The connected battery pack voltage passed through the power switch.
+5	Common 5 V converted from the Vcc line at Q1905 and Q1906 on the REG UNIT using IC1901 output as the reference voltage.
+5S	5 V controlled by the power saver function. This voltage is converted from the Vcc line at Q1901 and Q1902 on the REG UNIT using IC1902 output as the reference voltage.
R+5S	Receive 5 V controlled by the power saver function and SEND signal line. This voltage is converted from the Vcc line at Q1903 and Q1904 on the REG UNIT using IC1903 output as the reference voltage.
T+5	Transmit 5 V controlled by the TMUTE signal line. This voltage is converted from the Vcc line at Q1804 and Q1805 on the APC UNIT.
AF 8 V	AF amp power source controlled by the AF ON signal line. R1404/R1405 provides reference voltage.

4-4-2 CPU POWER SUPPLY CIRCUIT (LOGIC UNIT)

When the power switch is turned OFF, a voltage is applied to the CPU (IC3001) pin 73 via D3007 from the lithium backup battery (BT3001) installed in the transceiver to provide backup for the memory contents.



PLL CIRCUIT



4-4-3 +5S AND R+5S SWITCHING CIRCUITS (REG UNIT)

The IC-M7 has a power saver to reduce current consumption to approx. 1/4.

The PSC (Power Saver Control) signal is applied to IC1902. IC1902 controls +5S regulator (Q1901, Q1902, D1901) to turn ON and OFF +5S voltage.

PSC and SEND signals are applied to IC1903. IC1903 controls R+5S regulator (Q1903, Q1904, D1902). R+5S turns OFF during power saved period or transmitting.

4-4-4 CHARGING CIRCUIT (PRT UNIT)

Voltage from the [CHARGE] jack is applied to current control circuit (Q5001, Q5002, D5003, D5005) to charge an attached battery pack (except the BP-85). This circuit charges the battery pack in approx. 15 hours.

4-5 OTHER CIRCUITS

4-5-1 DISPLAY BACKLIGHT CIRCUIT (LOGIC UNIT)

When the [LIGHT] switch is pushed, pin 77 of the CPU outputs "HIGH." The signal is applied to Q3002 to light up the backlight LEDs (DS3002, DS3003).

4-5-2 CPU RESET CIRCUIT (LOGIC UNIT)

IC3002 detects +5 voltage. When the +5 voltage line becomes 5 V, IC3002 turns INT0 "HIGH" and the CPU (IC3001) restarts operation.

The CPU is reset when IC3001 pin 76 becomes "HIGH." The AND gate IC (IC3003) outputs a reset signal when both input terminals are "HIGH." One terminal is "HIGH" when the INTO just becomes "HIGH." The CPU is always reset when the power is turned ON.

4-5-3 TRANSMIT/RECEIVE INDICATOR CIRCUIT (LOGIC UNIT)

The transmit/receive indicator (DS3004) uses a 2-input LED and lights up in red or green.

The indicator lights up in red as the transmit indicator while transmitting using the T+5 voltage.

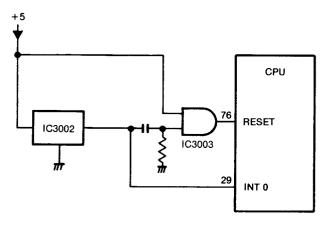
The indicator lights up in green as the busy indicator while the squelch opens using CPU pin 78 output via an inverter (Q3003).

4-6 CPU PORT ALLOCATIONS (LOGIC UNIT)

• INPUT PORT

PORT NUMBER	PIN NUMBER	DESCRIPTION
D4 [PTT]	1	Inputs a signal on the PTT line. This port becomes "LOW" when the PTT switch is pushed. This port is also used for cloning input.
D9 [FUNC]	6	Input port for the [FUNC] switch. (USA version: [LOCK] switch)
D10 [UNLOCK]	7	Detects a PLL unlock signal. When the signal is "HIGH," the PLL is unlocked.
D12, D13 [DIAL UP/DOWN]	9, 10	Input port for the up/down signal of the channel selector.
R01 [HI/LO]	16	Input port for the [HI/LOW] switch.
R10~R13 [KEYI0~ KEYI3]	19~22	These are input ports for the initial and key matrices.
R30 [BUSY]	27	Detects a squelch signal. The signal is "HIGH" when the squelch opens.
R32 [INT0]	29	Detects a signal for the standby mode of the CPU. The CPU enters the standby mode when the port becomes "LOW."
RESET	76	Inputs a signal for CPU resetting. The CPU program is reset when the port becomes "HIGH."

RESET CIRCUIT



• OUTPUT PORT

PORT NUMBER	PIN NUMBER	DESCRIPTION
D0 77 [LAMPO]		Becomes "HIGH" when the backlight LEDs light up.
D1 [BUSY LED]	78	Outputs a signal for lighting up in green the transmit/receive indicator. This port becomes "LOW" while receiving. (squelch opens)
D2 [HI/LOW]	79	This port become "HIGH" when LOW output power is selected.
D3 [CPC]	80	Outputs a control signal to cut off the loop filter while the power saver function is activated.
D5 [PSC]	2	This port becomes "HIGH" while the power saver function is activated.
D6~D8 [KEYS0~ KEYS2]	3~5	These are output ports for the initial and key matrices.
R00 [SCK]	15	Outputs clock signals for serial data.
R02 [SDATA]	17	Outputs serial data synchronized with the SCK signal.
R03 [PLSTB]	18	Outputs a strobe signal for serial data to the PLL IC.
R20 [TMUTE]	23	Outputs a control signal for T+5 V regulator.
R21 [SEND]	24	Outputs transmit/receive switching signals. This port becomes "HIGH" while transmitting.
R22 [AF ON]	25	Outputs an AF mute signal for AF power amplifier.
R23 [RMUTE]	26	Outputs a receive mute signal for the AF mute circuit. When emitting a beep tone, this port outputs the mute signal and the AF ON port does not output it.
R31 [BEEP]	28	Outputs a beep tone.

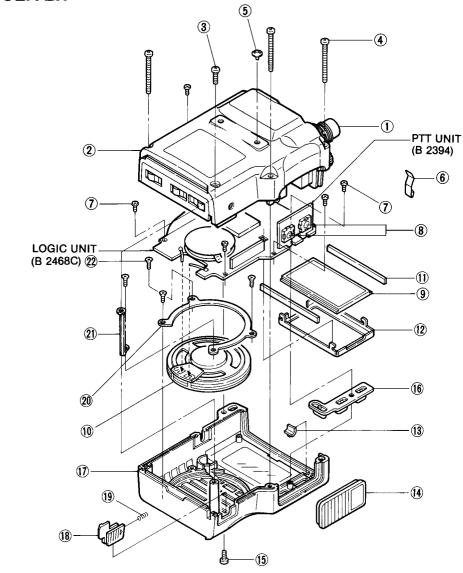
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SECTION 5 MECHANICAL PARTS AND DISASSEMBLY

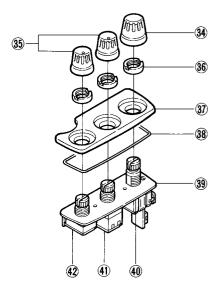
5-1 TRANSCEIVER

• CHASSIS



• MAIN UNIT 24) Ø 28 23) 29 25 27) 33 32) MAIN UNIT 30 (B 2382E) **3**

• TOP UNIT



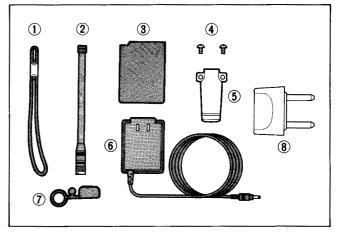
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LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.	LABEL NUMBER	ORDER NO.	DESCRIPTION	ΩΤΥ .
1	6510010950	ANT Connector TNC-R111	1	20	8930014810	752 SP plate	1
2	8010008631	752 Rear panel-1	1	21)	8930014830	Speaker ground lag	1
3	8810005710	Screw PH B0 M2 × 6 ZK	1	22	8810005740	Screw FH B0 No. 0 M2×3	4
4	8810005720	Screw PH B0 M2 × 20 ZK	3	23	8930014840	752 Module plate	1
5	8010007601	Bushing (A)-1	2	24	8810005860	Screw PH No. 0 M2 × 3 Ni	5
6	8930015651	LOGIC ground spring-1	1	25	2260001150	Switch [LIGHT] SW-103 (SKHUPC007B)	1
\bigcirc	8810001700	Screw PH B0 No. 0-3 M1.4×3	5	26	8810000120	Screw PH M2.6×3	1
(8)	2230000770	Switch [HI/LOW], [PTT] SW-104 (SKHUPE004B)	2	27	8810005700	Screw PH No. 0 M2×4 ZK	1
9	5030000550	LCD LD-BU9492J (incl. shield)	1	28	8930014971	752 Contact holder-1	1
10	2510000450	Speaker EAS-3P123D	1	29	8930014852	752 Battery terminal-2	3
1	8930014860	LCD contact strip SRCN-752	2	30	8510006130	758 PLL case	1
(12)	8930014870	752 LCD holder	1	31)	8510006490	861 PLL cover	1
(13)	8930014930	752 lens	1	32	8510005830	CO-PLL cover	1
(14)	8930017830	PTT switch (A) rubber	1	33	8930014911	LAMP switch-1 rubber	1
(15)	8810000100	Screw PH M2×4 ZK	1	34)	8610005790	Knob N147 [CHANNEL]	1
	0000047040	Front switch (A)-1 rubber		35	8610005780	Knob N146 [SQL, VOL]	2
16	8930017840	(FRA), (UK), (HOL), (EUR), (AUS), (GEN1), (GEN2), (ITA)	1	36	8830000550	VR nut (E)	3
	8930018420	Front switch (B)-1 rubber (USA)	1	37	8210005580	752 TOP panel (A)	1
	8210005721	752 Front panel (G)-1 (USA)	1	38	8930014950	752 TOP seal rubber	1
	8210005731	752 Front panel (H)-1	1	• 39	8930014801	752 VR plate-1	1
\bigcirc		(FRA), (UK), (HOL), (GEN2) 752 Front panel (F)-1		40	2260000890	Switch [CHANNEL] SRBM1L040A	1
	8210005780	(EUR), (AUS), (GEN1)	1	(41)	7210001440	Variable resistor [VOL] RK097111101NA (10KA)	1
	8210005890	752 Front panel (I)-1 (ITA)	1		7010001450	Variable resistor [SQL]	1
18	8930014922	752 Release button-2	1	42	7210001450	RK0971110051A (10KB)	'
(19)	8930014820	Release spring (M)	1				

Screw abbreviations PH: Pan head FH: Flat head B0: Self-tapping screw ZK: Black Ni: Nickel

5-2 ACCESSORIES

LABEL NUMBER	ORDER NO.	DESCRIPTION	QTY.
1	8010008970	Handstrap Belt HK-002	1
2	Optional product	FA-150T FLEXIBLE ANTENNA	1
. (6.600.00.000	Optional product	BC-73D (FRA), (HOL), (GEN2)	1
	Optional product	BC-73E (UK)	1
	Optional product	BC-74D (ITA)	1
3	Optional product	BM-76A (USA), (GEN1)	
	Optional product	BM-76E (AUS)	
	Optional product	BM-76V (EUR)	
4	8810005730	Screw BuH M3×3 ZK BS	2
5	8010008620	752 Belt clip	1
	Optional product	BP-82 (FRA), (UK), (HOL), (GEN2)	1
6	Optional product	BP-83 (ITA)	1
	Optional product	CM-89 (USA), (EUR), (AUS), (GEN1)	
\overline{O}	8930014960	752 Connector seal	
8	6910000090	#2505S/U Pin plug (UK), (AUS)	1



Screw abbreviations BuH: Button head ZK: Black

SECTION 6 PARTS LIST

[LOGIC UNIT]

[LOGIC UNIT]

REF.	ORDER		DESCRIPTION	REF.	ORDER	D	ESCRIPTION
NO.	NO.			NO.	NO. 7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
IC3001	1140001370	IC	HD404808A21H RH5VA42CA-T1	R3036 R3038	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
IC3002 IC3003	1180000610 1130003760	IC IC	TC4S81F (TE85R)	R3039	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
103003	1130003760	10	104301F (1E03H)	R3041	7030003830	Resistor	ERJ3GEYJ 185 V (1.8 MΩ)
					7030003830	Resistor	ERJ3GEYJ 224 V (220 kΩ)
				R3042	1		R20J 2.2 Ω
Q3001	1590000430	Transistor	DTC144EU T107	R3043	7010003870	Resistor	
Q3002	1530002060	Transistor	2SC4081 T107 R	R3044	7010003980	Resistor	R20J 18 Ω
Q3003	1590000720	Transistor	DTA144EU T107	R3045	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)
Q3005	1590000430	Transistor	DTC144EU T107	R3046	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)
Q3006	1590000430	Transistor	DTC144EU T107	R3047	7030003550	Resistor	ERJ3GEYJ 822 V (8.2 kΩ)
Q3007	1510000670	Transistor	2SA1588-GR (TE85R)			_	(France only)
				R3048	7030003600	Resistor	ERJ3GEYJ 223 V (22 kΩ)
D3001	1160000060	Diode	DAN202U T107	C3001	4030006850	Ceramic	C1608 JB 1H 471K-T-A
			(France, Europe)	C3002	4030006850	Ceramic	C1608 JB 1H 471K-T-A
	1750000160	Diode	DA114 T107 (U.K., Italy)	C3003	4030006850	Ceramic	C1608 JB 1H 471K-T-A
	1750000160	Diode	DA114 T107 (Italy)	C3004	4030006850	Ceramic	C1608 JB 1H 471K-T-A
D3002	1750000170	Diode	DA115 T107	C3005	4030006850	Ceramic	C1608 JB 1H 471K-T-A
I			(France, U.K., Europe)	C3006	4030006850	Ceramic	C1608 JB 1H 471K-T-A
	1160000060	Diode	DAN202U T107 (Holland)	C3007	4030006850	Ceramic	C1608 JB 1H 471K-T-A
	1750000170	Diode	DA115 T107 (Italy)	C3008	4030006850	Ceramic	C1608 JB 1H 471K-T-A
D3003	1750000170	Diode	DA115 T107	C3009	4030006640	Ceramic	C1608 SL 1H 180J-T-A
D3005	1750000170	Diode	DA115 T107	C3010	4030006640	Ceramic	C1608 SL 1H 180J-T-A
D3006	1750000130	Diode	DA204U T107	C3011	4030008630	Ceramic	C1608 JF 1C 104Z-T-A
D3007	1160000060	Diode	DAN202U T107	C3012	4550000770	Tantalum	TESVC 0J 226M-12L
D3008	1160000060	Diode	DAN202U T107	C3013	4030005110	Ceramic	C2012 JB 1E 473K-T-A
D3009	1750000160	Diode	DA114 T107 (U.S.A. only)	C3015	4030008630	Ceramic	C1608 JF 1C 104Z-T-A
				C3016	4030006860	Ceramic	C1608 JB 1H 102K-T-A
				C3017	4030006890	Ceramic	C1608 JF 1H 103Z-T-A
				C3018	4030006860	Ceramic	C1608 JB 1H 102K-T-A
X3001	6050006980	Crystal	CR-333 AT-38 4.182MHZ	C3019	4030006860	Ceramic	C1608 JB 1H 102K-T-A
				C3020	4030006860	Ceramic	C1608 JB 1H 102K-T-A
				C3021	4030006860	Ceramic	C1608 JB 1H 102K-T-A
R3001	7030003620	Resistor	ERJ3GEYJ 333 V (33 kΩ)		40000000000	ooranno	
	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)				
	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)				
	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)	DS3001	5030000550	LCD	LD-BU9492J (E-5134)
1 1	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)	DS3002	5040001260	LED	LN01301C (Q)
i i	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)	DS3003	5040001260	LED	LN01301C (Q)
1	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)	DS3004	5040001110	LED	SLM-23VMWS T97B
	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)				
	7310002770	Trimmer	RV-153				
	7030003320	Resistor	(RH03A3AN4X02A) 333 ERJ3GEYJ 101 V (100 Ω)	MC3001	7700000860	Microphone	WM-62A
	7310002720	Trimmer	RV-148				
			(RH03A3AS3X0DA) 472				
R3015	7030003280	Resistor	ERJ3GEYJ 470 V (47 Ω)	BT3001	3020000140	Lithium Battery	CH2320-1F42
1 1	7030003280	Resistor	ERJ3GEYJ 470 V (47 Ω) ERJ3GEYJ 472 V (4.7 kΩ)				
1 1	7030003520	Resistor	ERJ3GEYJ 222 V (2.2 kΩ)				
	7030003360	Resistor	ERJ3GEYJ 221 V (220 Ω)	S3001	2220000050	Switch	SSSS21148A
1 1	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)	53002	2260001150	Switch	SW-103 (SKHUPC007B)
	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)			. ,	[D/M (CALL)]
1 1	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)	1			[CH16/D] (U.S.A. only)
L (7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)	S3003	2260001150	Switch	SW-103 (SKHUPC007B)
	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)				[16 (DUAL)]
1 1	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)				[DUAL] (U.S.A. only)
1 1	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)	S3004	2260001150	Switch	SW-103 (SKHUPC007B)
1 1	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)			- 111011	[FUNC]
1 1	7030003840	Resistor	ERJ3GEYJ 105 V (1 MΩ)	I			[LOCK] (U.S.A. only)
	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)				· · · · · · · · · · · · · · · · · · ·
1 1	7030003800	Resistor	ERJ3GEYJ 105 V (1 MΩ)				1
	7030003800	Resistor	ERJ3GEYJ 562 V (1 MΩ)	1			
	7030003530	Resistor	ERJ3GEYJ 822 V (8.2 kΩ)	SP3001	2510000450	Speaker	EAS-3P123D
	7030003550	Resistor	ERJ3GEYJ 105 V (1 MΩ)				
	7030003800	Resistor	ERJ3GEYJ 224 V (220 kΩ)				
R3035							

[LOGIC UNIT]

REF. NO.	ORDER NO.	DESCRIPTION		
EP3001		P.C. Board	B 2468C (LOGIC)	
EP3002		F.P. Board	B 2108B (LOGIC to MAIN)	
EP3003		F.P. Board	B 2111B (LOGIC to ENC)	
EP3004		LCD Contact Strip	SR CN-752	

[MAIN UNIT]

REF. NO.	ORDER NO.	DESCRIPTION		
IC1001	1150000780	IC	SC1106	
Q1001	1530000370	Transistor	2SC3356-T2B	
Q1002	1530000370	Transistor	2SC3356-T2B	1
Q1003	1510000510	Transistor	2SA1576 T107 R	
Q1004	1590000430	Transistor	DTC144EU T107	
Q1005	1510000510	Transistor	2SA1576 T107 R	
Q1006	1530002560	Transistor	2SC4403-3-TR	
Q1007	1560000540	FET	2SK880-Y (TE85R)	1
Q1008	1530002560	Transistor	2SC4403-3-TR	
Q1009	1530002340	Transistor	2SC2954-T2B	
D1001	1790000450	Diode	MA862 (TX)	
D1002	175000080	Diode	1SS153-T2	
D1003	1790000490	Diode	HSM88AS-TR	
D1004	1790000490	Diode	HSM88AS-TR	
D1005	1790000590	Diode	MA110 (TW)	
D1006	1750000130	Diode	DA204U T107	1
D1007	1790000450	Diode	MA862 (TX)	
D1008	1790000540	Varicap	MA338 (TX)	
FI1001	2010000230	Filter	30M15B (FL-76)	
FILOUT	2010000230	FILO	30M108 (FE-70)	
X1001	6050004930	Crystal	CR-212	
X1001	000004900	Orystal	OFFETE	
L1001	6110002070	Coll	LA-227	
L1002	6110002120	Coll	LA-228	
L1002	6110002070	Coil	LA-227	
L1003	6110002000	Coll	LA-226	
L1004	6140000930	Coil	LR-116	
L1005	6150003570	Coil	LS-393	
L1008	6200000260	Coil	LON 2A RIOK	
L1009	6200000770	Coil	LQN 2A 68NM	
L1010	6110002070	Coll	LA-227	
L1011	6200000750	Coil	LQH 3N 4R7M	
R1001	7030003370	Resistor	ERJ3GEYJ 271 V (270 Ω)	
R1002	7030003280	Resistor	ERJ3GEYJ 470 V (47 Ω)	
R1003	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)	
R1004	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)	
R1005	7030003380	Resistor	ERJ3GEYJ 331 V (330 Ω)	
R1006	7030003380	Resistor	ERJ3GEYJ 331 V (330 Ω)	
R1007	7030003240	Resistor	ERJ3GEYJ 220 V (22 Ω)	
R1008	7030003240	Resistor	ERJ3GEYJ 220 V (22 Ω)	1

REF. ORDER DESCRIPTION NO. NO. ERJ3GEYJ 103 V (10 kΩ) 7030003560 R1009 Resistor 7030003400 Resistor ERJ3GEYJ 471 V (470 Ω) R1011 7030003400 Resistor ERJ3GEYJ 471 V (470 Ω) B1013 ERJ3GEYJ 471 V (470 Ω) R1014 7030003400 Resistor ERJ3GEYJ 103 V (10 kΩ) R1015 7030003560 Resistor ERJ3GEYJ 122 V (1.2 kΩ) R1016 7030003450 Resistor R1017 7030003440 Resistor ERJ3GEYJ 102 V (1 kΩ) 7030003440 Resistor ERJ3GEYJ 102 V (1 kQ) R1018 ERJ3GEYJ 104 V (100 kΩ) R1019 7030003680 Resistor R1020 7030003680 Resistor ERJ3GEYJ 104 V (100 kΩ) ERJ3GEYJ 101 V (100 Ω) 7030003320 Resistor R1021 R1022 7030003480 Resistor ERJ3GEYJ 222 V (2.2 kΩ) 7030003680 ERJ3GEYJ 104 V (100 kΩ) R1023 Resistor ERJ3GEYJ 224 V (220 kΩ) R1024 7030003720 Resistor ERJ3GEYJ 103 V (10 kΩ) R1025 7030003560 Resistor ERJ3GEYJ 223 V (22 kΩ) R1027 7030003600 Resistor R1029 7510000090 Thermistor ERT-D2FGL202S R1030 7030003620 Resistor ERJ3GEYJ 333 V (33 kΩ) ERJ3GEYJ 103 V (10 kΩ) R1031 7030003560 Resistor 7030003720 ERJ3GEYJ 224 V (220 kΩ) 033 Resistor ERJ3GEYJ 472 V (4.7 kΩ) 7030003520 Resistor 035 ERJ3GEYJ 472 V (4.7 kΩ) 036 7030003520 Resistor ERJ3GEYJ 472 V (4.7 kΩ) 037 7030003520 Resistor ERJ3GEYJ 470 V (47 Ω) 038 7030003280 Resistor 7030003410 ERJ3GEYJ 561 V (560 Ω) 039 Resistor 040 7030003320 Resistor ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 820 V (82 Ω) 041 7030003310 Resistor ERJ3GEYJ 100 V (10 Ω) 042 7030003200 Resistor ERJ3GEYJ 470 V (47 Ω) 043 7030003280 Resistor ERJ3GEYJ 100 V (10 Ω) 044 7030003200 Resistor ERJ3GEYJ 272 V (2.7 kΩ) 7030003490 Resistor 045 EBJ3GEYJ 331 V (330 Q) 046 7030003380 Resistor 047 7030003550 Resistor ERJ3GEYJ 822 V (8.2 kΩ) ERJ3GEYJ 272 V (2.7 kΩ) 7030003490 Resistor 048 049 7030003380 Resistor ERJ3GEYJ 331 V (330 Ω) 050 7030003340 Resistor ERJ3GEYJ 151 V (150 Ω) 7030003230 Resistor ERJ3GEYJ 180 V (18 Ω) 052 053 7030003370 Resistor ERJ3GEYJ 271 V (270 Ω) 054 7030003320 Resistor ERJ3GEYJ 101 V (100 Ω) ERJ3GEYJ 331 V (330 Ω) 7030003380 Resistor 055 7030003520 Resistor ERJ3GEYJ 472 V (4.7 kΩ) 056 ERJ3GEYJ 472 V (4.7 kΩ) 057 7030003520 Resistor 4030006610 C1608 SL 1H 100D-T-A 001 Ceramic C1608 SL 1H 040C-T-A 002 4030006550 Ceramic 4030006660 C1608 SL 1H 220J-T-A 003 Ceramic 004 4030008440 Ceramic C1608 SL 1H 1R5C-T-A C1608 SL 1H 120J-T-A 005 4030006620 Ceramic 006 4030006860 Ceramic C1608 JB 1H 102K-T-A C1608 SL 1H 180J-T-A 4030006640 007 Ceramic 800 4030006690 Ceramic C1608 SL 1H 330J-T-A C1608 SL 1H 150J-T-A 009 4030006630 Ceramic 4030006860 C1608 JB 1H 102K-T-A 010 Ceramic 011 4030006860 Ceramic C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A 012 4030006860 Ceramic C1608 SL 1H 220J-T-A 013 40300066660 Ceramic 4030006860 Ceramic C1608 JB 1H 102K-T-A 014 C1608 SL 1H 120J-T-A 4030006620 Ceramic 015 TEMSVB2 0J 106M-8L 016 4550003040 Tantalum 017 4030006860 Ceramic C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A 4030006860 Ceramic 019 020 4030006860 Ceramic C1608 JB 1H 102K-T-A 021 4030008630 Ceramic C1608 JF 1C 104Z-T-A C1608 JB 1H 102K-T-A 4030006860 Ceramic 022 C1608 SL 1H 221J-T-A 023 4030006800 Ceramic 024 4030006750 Ceramic C1608 SL 1H 101J-T-A ECRGA015E30 025 4610000300 Trimmer C1608 CH 1H 120J-T-A 026 4030007020 Ceramic C1608 CH 1H 360J-T-A 027 4030008750 Ceramic C1608 JB 1H 102K-T-A 4030006860 Ceramic 028

[MAIN UNIT]

[MAIN UNIT]

[AF UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
C1030	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1034	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1035	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1036	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1037	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1038	4030006890	Ceramic	C1608 JF 1H 103Z-T-A
C1039	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1040	4030006600	Ceramic	C1608 SL 1H 090D-T-A
C1041	4030006890	Ceramic	C1608 JF 1H 103Z-T-A
C1042	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1043	4030006640	Ceramic	C1608 SL 1H 180J-T-A
C1044	4510001350	Electrolytic	16 MS5 10 μF
C1045	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1046	4510003160	Electrolytic	16 RC2 22 μF (D=4.0)
C1047	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1048	4030006640	Ceramic	C1608 SL 1H 180J-T-A
C1049	4030006640	Ceramic	C1608 SL 1H 180J-T-A
C1050	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1051	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1052	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1053	4510001380	Electrolytic	25 MS5 4R7 μF
C1058	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1059	4550002890	Tantalum	TESVA 1A 225M1-8L
C1060	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1061	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1062	4550002890	Tantalum	TESVA 1A 225M1-8L
C1063	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1065	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1066	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1067	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1070	4030006860	Ceramic	C1608 JB 1H 102K-T-A
EP1001	0910025325	P.C. Board	B 2382E (MAIN)

REF. NO.	ORDER NO.		DESCRIPTION
B1407	7030003760	Resistor	ERJ3GEYJ 474 V (470 kΩ)
R1407	7030003710	Resistor	ERJ3GEYJ 184 V (180 kΩ)
R1408	7030003480	Resistor	ERJ3GEYJ 222 V (2.2 kΩ)
R1409 R1410	7030003480	Resistor	ERJ3GEYJ 273 V (27 kΩ)
R1410	7030003610	Resistor	ERJ3GEYJ 273 V (27 kΩ)
R1411	7030003480	Resistor	ERJ3GEYJ 222 V (2.2 kΩ)
R1412 R1413	7030003480	Resistor	ERJ3GEYJ 105 V (1 MΩ)
R1413	7030003320	Resistor	ERJ3GEYJ 101 V (100 Ω)
R1414	7030003340	Resistor	ERJ3GEYJ 151 V (150 Ω)
R1415	7030003200	Resistor	ERJ3GEYJ 100 V (10 Ω)
R1410	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
R1417	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R1418	7030003720	Resistor	ERJ3GETJ 224 V (220 K12)
C1401	4550000280	Tantalum	TESVB2 1A 475M-8L
C1402	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1403	4510001340	Electrolytic	10 MS5 33 μF
C1404	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1405	4030006900	Ceramic	C1608 JB 1E 103K-T-A
C1406	4030006900	Ceramic	C1608 JB 1E 103K-T-A
C1407	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1408	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1409	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1411	4030008630	Ceramic	C1608 JF 1C 104Z-T-A
C1412	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1413	4030006710	Ceramic	C1608 SL 1H 470J-T-A
C1414	4550003040	Tantalum	TEMSVB2 0J 106M-8L
C1415	4030005110	Ceramic	C2012 JB 1E 473K-T-A
C1416	4510002740	Electrolytic	10 SS 220 μF
C1417	4550000550	Tantalum	TESVA 1V 224M1-8L
C1418	4030008630	Ceramic	C1608 JF 1C 104Z-T-A
EP1401	0910025422	P.C. Board	B 2386B (AF)
EP1402	6910003110	Lead Frame	HFB2.0-0.7-8 (N)

[AF UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
IC1401	1110001810	IC	TA7368F (TP1)
Q1401	1530002060	Transistor	2SC4081 T107 R
Q1402	1530002060	Transistor	2SC4081 T107 R
Q1403	1520000270	Transistor	2SB1182 T201 Q
Q1404	1530002060	Transistor	2SC4081 T107 R
Q1405	1530002060	Transistor	2SC4081 T107 R
Q1406	1590000520	FET	2SJ106-GR (TE85R)
D1401	1160000060	Diode	DAN202U T107
R1401	7030003760	Resistor	ERJ3GEYJ 474 V (470 kΩ)
R1402	7030003600	Resistor	ERJ3GEYJ 223 V (22 kΩ)
R1403	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
R1404	7030003420	Resistor	ERJ3GEYJ 681 V (680 Ω)
R1405	7030003430	Resistor	ERJ3GEYJ 821 V (820 Ω)
R1406	7030003630	Resistor	ERJ3GEYJ 393 V (39 kΩ)

[MIC UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
IC1501	1110001540	IC	M5218FP-71A
Q1501	1590000430	Transistor	DTC144EU T107
Q1502	1590000720	Transistor	DTA144EU T107
DIFOI		Desister	
R1501	7030003730	Resistor	ERJ3GEYJ 274 V (270 kΩ)
R1502	7030003880	Resistor	ERJ3GEYJ 244 V (240 kΩ)
R1503	7030003370	Resistor	ERJ3GEYJ 271 V (270 Ω)
R1504	7030003690	Resistor	ERJ3GEYJ 124 V (120 kΩ)
R1505	7030003670	Resistor	ERJ3GEYJ 823 V (82 kΩ)
R1506	7030003670	Resistor	ERJ3GEYJ 823 V (82 kΩ)
R1507	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
R1508	7510000180	Thermistor	DTN-T203S223LS (T)
R1509	7030003540	Resistor	ERJ3GEYJ 682 V (6.8 kΩ)
R1510	7030003570	Resistor	ERJ3GEYJ 123 V (12 kΩ)
R1511	7310002600	Trimmer	RV-110
			(RH03A3AS4X0AA) 473

[MIC UNIT]

[DETA	UNIT]
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REF. NO.	ORDER NO.		DESCRIPTION
R1512	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)
R1513	7030003710	Resistor	ERJ3GEYJ 184 V (180 kΩ)
R1514	7310002790	Trimmer	RV-155 (RH03A3AE5J 154)
R1515	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R1516	7030003730	Resistor	ERJ3GEYJ 274 V (270 kΩ)
R1517	7030003730	Resistor	ERJ3GEYJ 274 V (270 kΩ)
C1501 C1502 C1503 C1504 C1505 C1506 C1507 C1508 C1509 C1510 C1511 C1512 C1513	4030006470 4030006860 4030006850 4030006850 4550000530 4030008650 4030006740 4030006880 4030006850 4510001850 4030006850 4030006860	Ceramic Ceramic Ceramic Ceramic Tantalum Ceramic Ceramic Ceramic Electrolytic Ceramic Ceramic Ceramic	C2012 JB 1H 153K-T-A C1608 JB 1H 102K-T-A C2012 JB 1H 153K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A TESVA 1V 104M1-8L C1608 JB 1H 332K-T-A C1608 JB 1H 322K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A C1608 JB 1H 102K-T-A
EP1501	0910024931	P.C. Board	B 2387A (MIC)
EP1502	6910003110	Lead Frame	HFB2.0-0.7-8 (N)

[DETA UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
IC1301	1120001650	IC	TK10487MT1
Q1301	1530002020	Transistor	2SC3770-3-TA
D1301	1790000490	Diode	HSM88AS-TR
D1302	1750000130	Diode	DA204U T107
			•
FI1301	2020000550	Ceramic Filter	
FI1302	2020000550	Ceramic Filter	CFUM455E
X1301 X1302	6070000060 6050005010	Discriminator Crystal	CDBM455C7 CR-214
R1301	7030003480	Resistor	ERJ3GEYJ 222 V (2.2 kΩ)
R1302	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)
R1303	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)
R1304	7030003460	Resistor	ERJ3GEYJ 152 V (1.5 kΩ)
R1305	7030003400	Resistor	ERJ3GEYJ 471 V (470 Ω)
R1306	7030003730	Resistor	ERJ3GEYJ 274 V (270 kΩ)
R1307	7030003730	Resistor	ERJ3GEYJ 274 V (270 kΩ)
R1308	7030003480	Resistor	ERJ3GEYJ 222 V (2.2 kΩ)
R1309	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ) ERJ3GEYJ 104 V (100 kΩ)
R1310 R1311	7030003680 7030003480	Resistor Resistor	ERJ3GEYJ 222 V (2.2 kΩ)

REF. NO.	ORDER NO.		DESCRIPTION
R1312	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)
R1313	7030003400	Resistor	ERJ3GEYJ 471 V (470 Ω)
R1314	7030003400	Resistor	ERJ3GEYJ 471 V (470 Ω)
R1315	7030003670	Resistor	ERJ3GEYJ 823 V (82 kΩ)
R1316	7030003430	Resistor	ERJ3GEYJ 821 V (820 Ω)
R1317	7030003550	Resistor	ERJ3GEYJ 822 V (8.2 kΩ)
R1318	7030003710	Resistor	ERJ3GEYJ 184 V (180 kΩ)
R1319	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)
R1320	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)
R1321	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)
C1301	4030008630	Ceramic	C1608 JF 1C 104Z-T-A
C1302	4030006740	Ceramic	C1608 SL 1H 820J-T-A
C1303	4030008630	Ceramic	C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A
C1304	4030008630	Ceramic	
C1305	4030008630	Ceramic	C1608 JF 1C 104Z-T-A
C1306	4030006640	Ceramic	C1608 SL 1H 180J-T-A C1608 SL 1H 560J-T-A
C1307	4030006720	Ceramic	
C1308	4030006860	Ceramic	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C1309	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1310 C1311	4030006860 4030006860	Ceramic Ceramic	C1608 JB 1H 102K-T-A
C1311	4030006690	Ceramic	C1608 SL 1H 330J-T-A
C1312	4030008630	Ceramic	C1608 JF 1C 104Z-T-A
C1313	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1315	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1316	4550000550	Tantalum	TESVA 1V 224M1-8L
C1318	4550000550	Tantalum	TESVA 1V 224M1-8L
C1319	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1320	4030006890	Ceramic	C1608 JF 1H 103Z-T-A
C1321	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1322	4030006890	Ceramic	C1608 JF 1H 103Z-T-A
C1323	4030008630	Ceramic	C1608 JF 1C 104Z-T-A
EP1301	0910025772	P.C. Board	B 2590B (DETA)
EP1302	6910003110	Lead Frame	HFB2.0-0.7-8 (N)
		6 6 7	

[APC UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
Q1801	1520000270	Transistor	2SB1182 T201 Q
Q1802	1530002280	Transistor	2SC4081 T107 S
Q1803	1590000620	Transistor	FMS1 T148
Q1804	1520000270	Transistor	2SB1182 T201 Q
Q1805	1530002280	Transistor	2SC4081 T107 S
D1801	1160000050	Diode	DAP202U T107
R1802	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)
R1803	7030003770	Resistor	ERJ3GEYJ 564 V (560 kΩ)
R1804	7030003720	Resistor	ERJ3GEYJ 224 V (220 kΩ)
R1806	7030003670	Resistor	ERJ3GEYJ 823 V (82 kΩ)
R1808	7030003590	Resistor	ERJ3GEYJ 183 V (18 kΩ)
R1809	7030003600	Resistor	ERJ3GEYJ 223 V (22 kΩ)

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[APC UNIT]

[PLL VCO UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
R1810	7030003480	Resistor	ERJ3GEYJ 222 V (2.2 kΩ)
C1801	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1802	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1805	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1806	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1807	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1808	4030006850	Ceramic	C1608 JB 1H 471K-T-A
C1809	4030006850	Ceramic	C1608 JB 1H 471K-T-A
EP1801	0910026230	P.C. Board	B 2391 (APC)
EP1802	6910003110	Lead Frame	HFB2.0-0.7-8 (N)
1			

[REG UNIT]

		1		1 I	L1603	620
REF. NO.	ORDER NO.		DESCRIPTION		L1604 L1605	620 613
IC1901	1180000530	IC	S-81250HG-RD-T1		L1606	620
IC1901	1130004170		TC4S01F (TE85R)		L1607	620
IC1902	1130004170		TC4S01F (TE85R)	1 1	L1608	620
10 1903	1130004170				21000	
Q1901	1530002280	Transistor	2SC4081 T107 S		R1601	703
Q1902	1510000510	Transistor	2SA1576 T107 R		R1602	703
Q1903	1530002280	Transistor	2SC4081 T107 S	1 1	R1603	70:
Q1904	1510000500	Transistor	2SA1162-GR (TE85R)		R1604	70
Q1905	1530002280	Transistor	2SC4081 T107 S	1 1	R1605	70
Q1906	1520000200	Transistor	2SB798-T2 DK		R1606	70:
				1 1	R1607	70:
		{			R1608	70:
D1901	1750000160	Diode	DA114 T107		R1609	70:
D1902	1790000590	Diode	MA110 (TW)		R1610	70:
D1903	1160000060	Diode	DAN202U T107		R1611	70
		[R1612	70
					R1613	70
R1901	7030003400	Resistor	ERJ3GEYJ 471 V (470 Ω)		R1614	70
R1902	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)		R1615	70:
R1903	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)		R1616	70:
R1904	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)		R1617	70:
R1905	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)		R1618	70
					R1619	70
					R1620	70
C1901	4510001360	Electrolytic	16 MS5 22 μF			
C1902	4030006850	Ceramic	C1608 JB 1H 471K-T-A			
C1903	4510003190	Electrolytic	6.3 RC2 47 μF (D=4.0)		C1601	403
C1904	4030006850	Ceramic	C1608 JB 1H 471K-T-A		C1602	403
C1905	4510001320	Electrolytic	6R3 MS5 47 μF	1 1	C1603	40:
C1906	4030006850	Ceramic	C1608 JB 1H 471K-T-A		C1604	403
C1907	4030006850	Ceramic	C1608 JB 1H 471K-T-A		C1605	40
C1908	4030006850	Ceramic	C1608 JB 1H 471K-T-A		C1606	45
C1909	4030006850	Ceramic	C1608 JB 1H 471K-T-A		C1607	40
C1910	4510003190	Electrolytic	6.3 RC2 47 μF (D=4.0)		C1608	40
C1911	4030006850	Ceramic	C1608 JB 1H 471K-T-A		C1609	40
					C1610	403
					C1611	40
EP1901	0910026170	P.C. Board	B 2392 (REG)		C1612	40
EP1902	6910003110	Lead Frame	HFB2.0-0.7-8 (N)	1 1	C1613	40
				1 1	C1614	40
		1			C1615	40
					C1616	40:
				1	C1617	40:
		1		1 1	C1618	403

REF.	ORDER	DESCRIPTION		
NO.	NO.			
IC1601 IC1602	1140001310 1130004200		MB1504PF-G-BND TC4S66F (TE85R)	
Q1601	1590000970	Transistor	FMA2 T148	
Q1602	1590000430	Transistor	DTC144EU T107	
Q1603	1590000440	Transistor Transistor	DTA143ZU T107 2SA1576 T107 S	
Q1604 Q1605	1510000620 1530002280	Transistor	2SC4081 T107 S	
Q1606	1560000340	FET	2SK210-Y (TE85R)	
Q1607	1560000340	FET	2SK210-Y (TE85R)	
Q1608	1530002560	Transistor	2SC4403-3-TR	
Q1609	1530002560	Transistor	2SC4403-3-TR	
Q1610	1530002560	Transistor	2SC4403-3-TR	
D1601	1790000640	Varicap	MA363B (TX)	
D1602	1790000640	Varicap	MA363B (TX)	
D1603	1790000640	Varicap	МАЗ6ЗВ (ТХ)	
L1601	6200000750	Coil	LQH 3N 4R7M	
L1602	6130002360	Coll	LB-257	
L1603	620000750 620000750	Coll Coll	LQH 3N 4R7M LQH 3N 4R7M	
L1604 L1605	6130002370	Coil	LB-258	
L1606	6200000750	Coll	LQH 3N 4R7M	
L1607	6200000260	Coil	LQN 2A R10K	
L1608	6200000260	Coil	LQN 2A R10K	
R1601	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)	
R1602	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)	
R1603	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ)	
R1604	7030003640	Resistor	ERJ3GEYJ 473 V (47 kΩ)	
R1605	7030003560	Resistor	ERJ3GEYJ 103 V (10 kΩ) ERJ3GEYJ 102 V (1 kΩ)	
R1606 R1607	7030003440 7030003390	Resistor Resistor	ERJ3GEYJ 391 V (390 Ω)	
R1608	7030003550	Resistor	ERJ3GEYJ 822 V (8.2 kΩ)	
R1609	7030003310	Resistor	ERJ3GEYJ 820 V (82 Ω)	
R1610	7030003260	Resistor	ERJ3GEYJ 330 V (33 Ω)	
R1611	7030003660	Resistor	ERJ3GEYJ 683 V (68 kΩ)	
R1612	7030003420	Resistor	ERJ3GEYJ 681 V (680 Ω) ERJ3GEYJ 681 V (680 Ω)	
R1613 R1614	7030003420 7030003660	Resistor Resistor	ERJ3GEYJ 683 V (68 kΩ)	
R1615	7030003650	Resistor	ERJ3GEYJ 563 V (56 kΩ)	
R1616	7030003390	Resistor	ERJ3GEYJ 391 V (390 Ω)	
R1617	7030003680	Resistor	ERJ3GEYJ 104 V (100 kΩ)	
R1618	7030003610	Resistor	ERJ3GEYJ 273 V (27 kΩ)	
R1619 R1620	7030003680 7030003680	Resistor Resistor	ERJ3GEYJ 104 V (100 kΩ) ERJ3GEYJ 104 V (100 kΩ)	
C1601	4030008630	Ceramic	C1608 JF 1C 104Z-T-A	
C1602	4030006860	Ceramic	C1608 JB 1H 102K-T-A	
C1603	4030008630	Ceramic	C1608 JF 1C 104Z-T-A	
C1604	4030008630	Ceramic	C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A	
C1605 C1606	4030008630 4550003080	Ceramic Tantalum	TEMSVA 1A 335M-8L	
C1608	4030006900	Ceramic	C1608 JB 1E 103K-T-A	
C1608	4030006670	Ceramic	C1608 SL 1H 270J-T-A	
C1609	4030006570	Ceramic	C1608 SL 1H 060D-T-A	
C1610	4030006550	Ceramic	C1608 SL 1H 040C-T-A	
C1611	4030006860	Ceramic	C1608 JB 1H 102K-T-A C1608 SL 1H 0R5C-T-A	
C1612 C1613	4030006510 4030006510	Ceramic Ceramic	C1608 SL 1H 0R5C-T-A	
C1613	4030006750	Ceramic	C1608 SL 1H 101J-T-A	
C1615	4030006520	Ceramic	C1608 SL 1H 010C-T-A	
C1616	4030006550	Ceramic	C1608 SL 1H 040C-T-A	
C1617	4030006540	Ceramic	C1608 SL 1H 030C-T-A	
C1618	4030008630	Ceramic	C1608 JF 1C 104Z-T-A	

[PLL VCO UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
C1619	4030006510	Ceramic	C1608 SL 1H 0R5C-T-A
C1620	4030006510	Ceramic	C1608 SL 1H 0R5C-T-A
C1621	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1622	4030006550	Ceramic	C1608 SL 1H 040C-T-A
C1623	4030006580	Ceramic	C1608 SL 1H 070D-T-A
C1624	4030006580	Ceramic	C1608 SL 1H 070D-T-A
C1625	4030006620	Ceramic	C1608 SL 1H 120J-T-A
C1626	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1627	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C1628	4550000460	Tantalum	TESVA 1C 105M1-8L
EP1601	0910025372	P.C. Board	B 2583B (PLL VCO)

[RFA UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
Q1201	1560000550	FET	2SK882-Y (TE85R)
D1201	1790000640	Varicap	MA363B (TX)
D1202	1790000640	Varicap	MA363B (TX)
D1203	1790000640	Varicap	MA363B (TX)
D1204	1790000640	Varicap	MA363B (TX)
R1201	7030003700	Resistor	ERJ3GEYJ 154 V (150 kΩ)
R1202	7030003700	Resistor	ERJ3GEYJ 154 V (150 kΩ)
R1203	7030003230	Resistor	ERJ3GEYJ 180 V (18 Ω)
R1204	7030003700	Resistor	ERJ3GEYJ 154 V (150 kΩ)
R1205	7030003700	Resistor	ERJ3GEYJ 154 V (150 kΩ)
R1206	7030003320	Resistor	ERJ3GEYJ 101 V (100 Ω)
C1201 C1202 C1203 C1204 C1205 C1206 C1207 C1208 C1209 C1210 C1211 C1212 C1214 C1215 C1216 C1217	4030006700 4030006540 4030008570 4030006860 4030006860 4030006510 4030006510 4030006510 4030006540 4030006560 4030006560 4030006560 4030006550 4030006560	Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic Ceramic	C1608 SL 1H 390J-T-A C1608 SL 1H 030C-T-A C1608 SL 1H R75C-T-A C1608 SL 1H R75C-T-A C1608 JB 1H 100D-T-A C1608 JB 1H 102K-T-A C1608 SL 1H 080D-T-A C1608 SL 1H 080C-T-A C1608 SL 1H 087C-T-A C1608 SL 1H 030C-T-A C1608 SL 1H 050C-T-A C1608 SL 1H 050C-T-A
EP1201	0910024772	P.C. Board	B 2383B (RFA)
EP1202	6910003110	Lead Frame	HFB2.0-0.7-8 (N)

[RFB UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
L1251	6150003580	Coil	LS-394
L1252	6150003590	Coil	LS-395
L1253	6150003600	Coil	LS-404
L1254	6150003590	Coil	LS-395
EP1251	0910024811	P.C. Board	B 2384A (RFB)

[ENC UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
D3201	1160000050	Diode	DAP202U T107
C3201 C3202	4030006850 4030006850	Ceramic Ceramic	C1608 JB 1H 471K-T-A C1608 JB 1H 471K-T-A
S3201 S3202	2260000890 2260001150	Encoder Switch	SRBM1L040A [CHANNEL] SW-103 (SKHUPC007B) [LIGHT (LOCK)] [LIGHT] (U.S.A. only)
EP3201	0910026181	P.C. Board	B 2395A (ENC)

[VR UNIT]

Γ	REF. NO.	ORDER NO.	D	ESCRIPTION
Γ	R4001	7210001440	Variable Resistor	RK097111101NA (10KA) [VOL]
	R4002	7210001450	Variable Resistor	
	C4001	4510002650	Electrolytic	16 MS7 100 μF
	C4002	4030006860	Ceramic	C1608 JB 1H 102K-T-A
	C4003	4030006860	Ceramic	C1608 JB 1H 102K-T-A
	EP4001	0910026192	P.C. Board	B 2396B (VR)
L				

[PTT UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
S3101	2230000770	Switch	SW-104 (SKHUPE004B) [HI/LOW]
S3102	2230000770	Switch	SW-104 (SKHUPE004B) [PTT]
EP3101	0910026690	P.C. Board	B 2394 (PTT)

[PRT UNIT]

REF. NO.	ORDER NO.		DESCRIPTION
Q5001	1520000200	Transistor	2SB798-T2 DK
Q5002	1530002280	Transistor	2SC4081 T107 S
D5001	1730000970	Zener	RD15M-T2B2
D5002	1790000670	Diode	SB07-03C-TA
D5003	1790000670	Diode	SB07-03C-TA
D5004	1790000590	Diode	MA110 (TW)
D5005	1730002160	Zener	02CZ5.1-Z (TE85R)
R5001	7030003250	Resistor	ERJ3GEYJ 270 V (27 Ω)
R5002	7030003250	Resistor	ERJ3GEYJ 270 V (27 Ω)
R5003	7030003380	Resistor	ERJ3GEYJ 331 V (330 Ω)
R5004	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)
R5005	7030003600	Resistor	ERJ3GEYJ 223 V (22 kΩ)
R5006	7030003520	Resistor	ERJ3GEYJ 472 V (4.7 kΩ)
R5007	7030000420	Resistor	MCR10EZHJ 2.2 kΩ (222)
R5008	7030003320	Resistor	ERJ3GEYJ 101 V (100 Ω)
R5009	7030003440	Resistor	ERJ3GEYJ 102 V (1 kΩ)
05004			
C5001	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C5002	4030006860	Ceramic	C1608 JB 1H 102K-T-A
C5003 C5004	4030006710 4030006860	Ceramic Ceramic	C1608 SL 1H 470J-T-A C1608 JB 1H 102K-T-A
C5004 C5005	4030006860	Ceramic	C1608 JB 1H 102K-T-A
0.5005	4030000000	Gerannic	01000 00 111 10210174
EP5001	0910026111	P.C. Board	B 2397A (PRT)

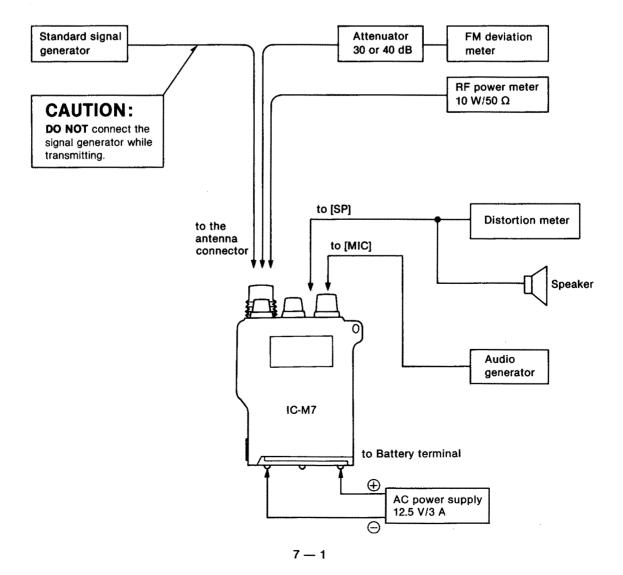
SECTION 7 ADJUSTMENT PROCEDURES

7-1 PREPARATION BEFORE SERVICING

REQUIRED TEST EQUIPMENT

EQUIPMENT	GRADE A	ND RANGE	EQUIPMENT	GRADE	AND RANGE
AC power supply	1	ut voltage : 12.5 V DC	AC milli-voltmeter	Measuring range	: 10 mV~10 V
	Current capacity	: 3 A or more	External speaker	Impedance	:8Ω
RF power meter (terminated type)	Frequency range	: 1~10 W : 140~180 MHz : 50 Ω	Audio generator	Frequency range Output level	: 300~3000 Hz : 1~500 mV
	SWR	: Less than 1.2 : 1	Attenuator	Power attenuation Capacity	: 30 or 40 dB : 10 W or more
Frequency counter	Frequency accuracy : ±1 ppm or be	: 0.1~180 MHz : ±1 ppm or better	Distortion meter	Measuring range	: 0.1~20 %
		100 mV or better	FM deviation meter	Frequency minimun	n : 180 MHz
Oscilloscope	1	: DC~20 MHz : 0.01~10 V		Measuring range : 0~±	: 0∼±10 kHz
Standard signal generator (SSG)		: 0.1~180 MHz : -127~-17 dBm (0.1 µV~32 mV)			

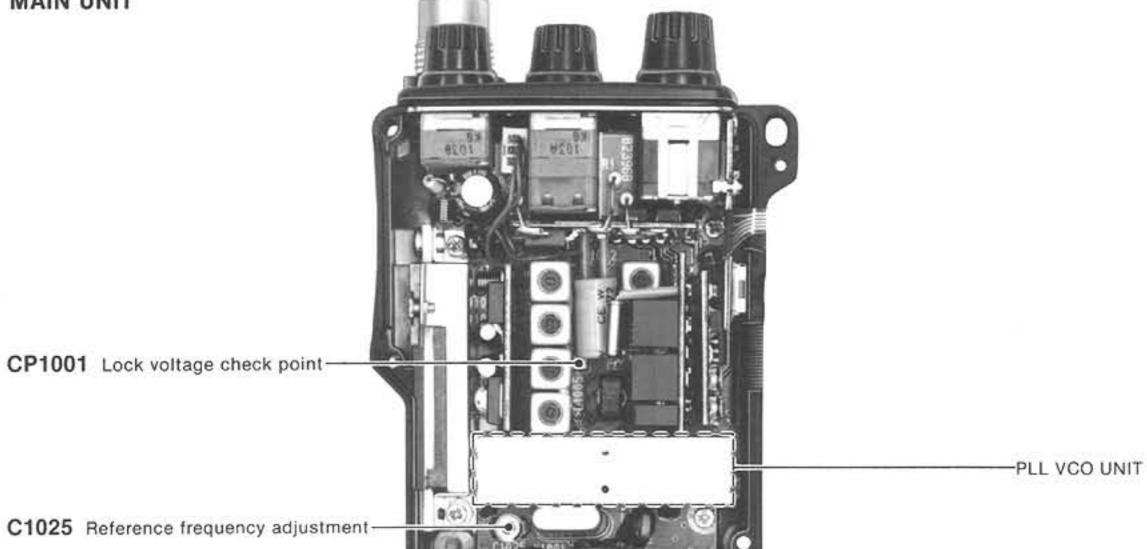
CONNECTION



7-2 PLL ADJUSTMENT

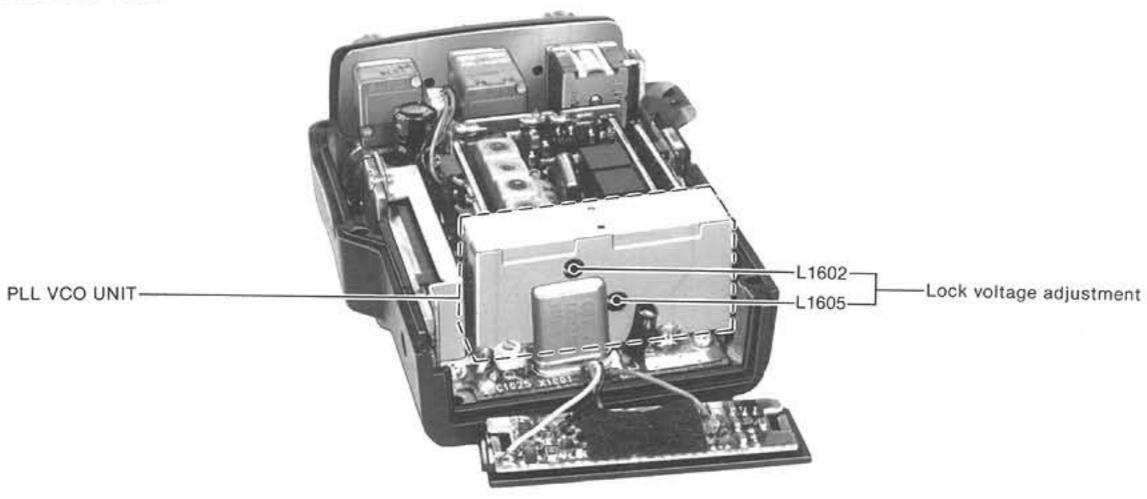
ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
			UNIT	LOCATION	VALUE	UNIT	ADJUST
LOCK VOLTAGE	1	 Operating channel : 16 Receiving 	PLL	Connect the oscilloscope to CP1001.	1.8 V DC	PLL VCO	L1602
	2	Transmitting			2.8 V DC		L1605
REFERENCE	1	 Operating channel : 16 Connect a 50 Ω dummy load. Transmitting 	Top panel	Loose couple the frequency counter to the dummy load.	156.800 MHz	MAIN	C1025

MAIN UNIT





PLL VCO UNIT

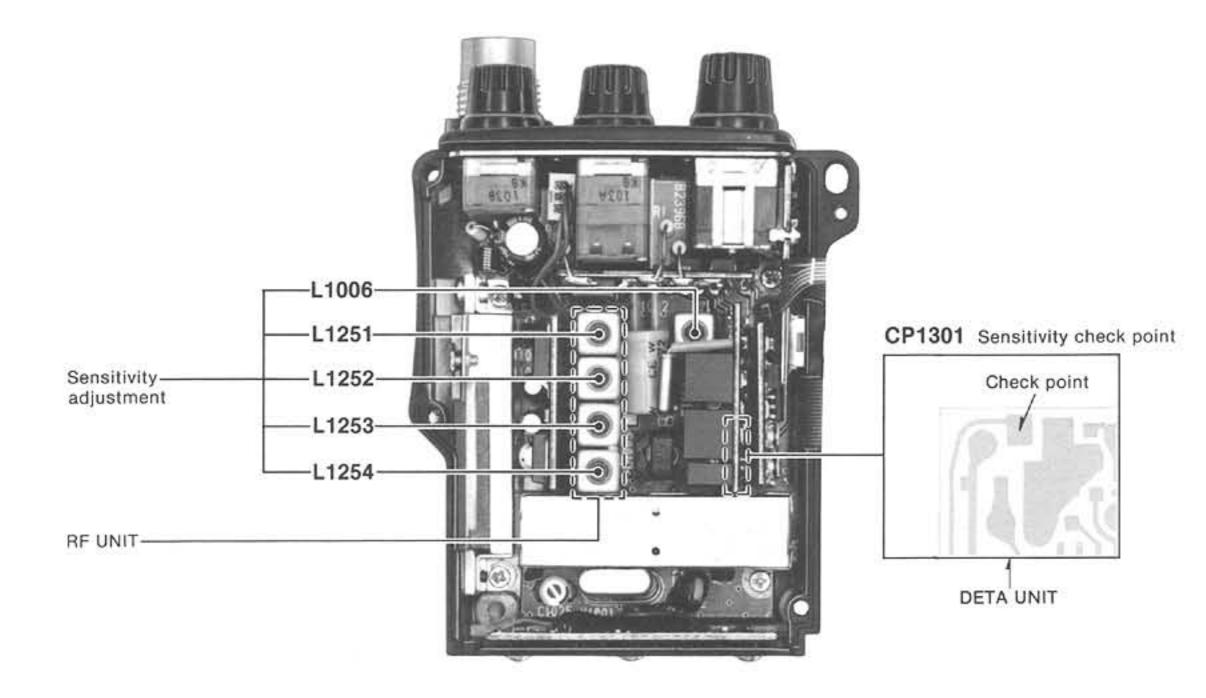


7-3 RECEIVER ADJUSTMENT

ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT	
			UNIT	LOCATION	THEOL	UNIT	ADJUST
SENSITIVITY	1	 Operating channel : 16 Apply an RF signal to the antenna connector. Frequency: 156.800 MHz Level : 0.35 µV (-116 dBm) 	DETA	Connect the oscilloscope to CP1301.	Pre-set to the top of the coil case.	RF	L1251, L1252, L1253, L1254
	2	Mod. : 1 kHz Dev. : ±3.5 kHz • [SQL] control : Max. CCW • Receiving			Maximum level		Adjust in sequence L1251, L1252, L1253, L1254
						MAIN	L1006
	3	 Adjust SSG output level so that SINAD level becomes 12 dB. 	Top panel	Connect the distortion meter with the 8 Ω load to the [SP] jack.	Applied RF signal level is less than 0.35 μV (-116 dBm).		Verify

CCW: Counterclockwise

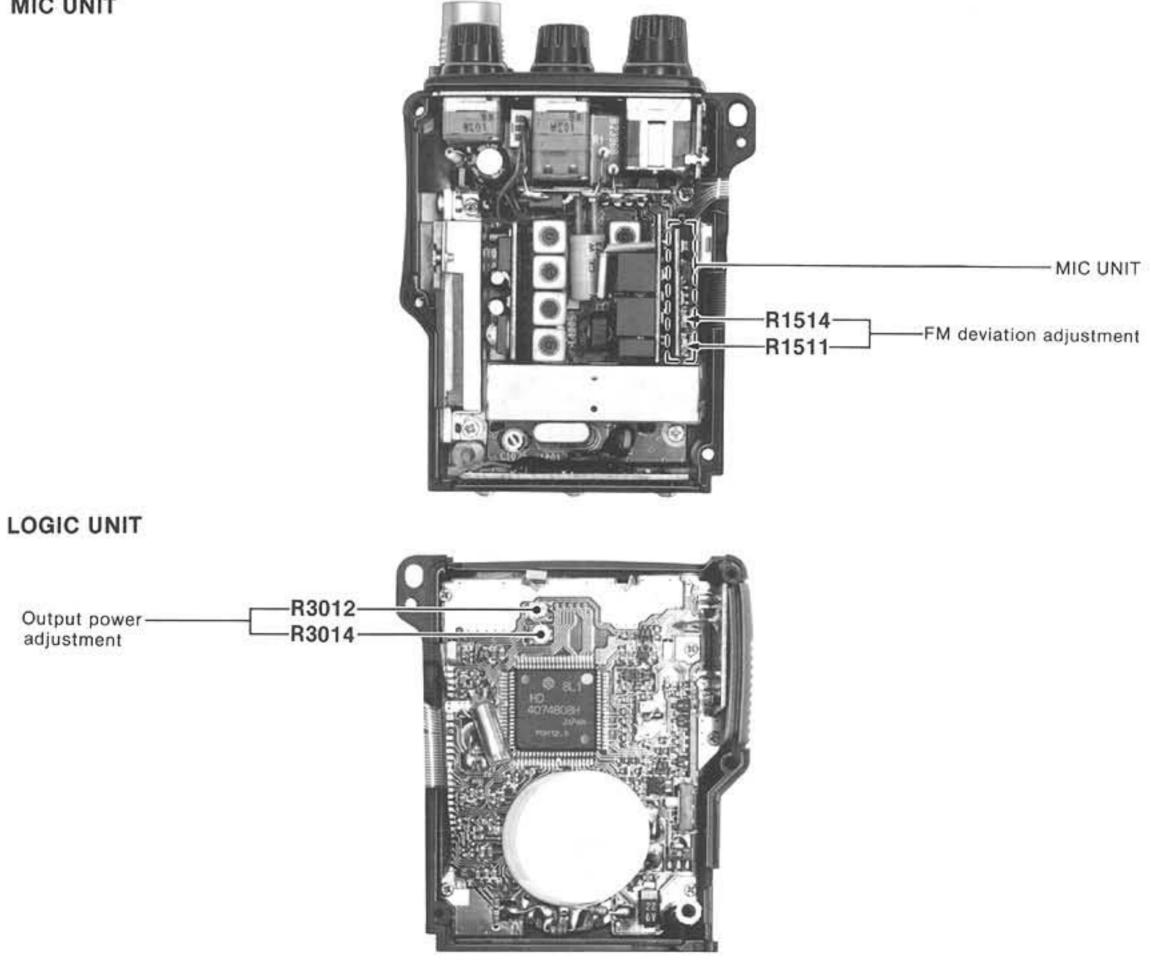
MAIN, DETA AND RF UNITS



7-4 TRANSMITTER ADJUSTMENT

ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT		VALUE	ADJUSTMENT POINT	
			UNIT	LOCATION	VALUE	UNIT	ADJUST
OUTPUT POWER	1	Operating channel : 16 [HI/LOW] switch : HI Transmitting	Top panel	Connect the RF power meter to the antenna connector.	5.0 W (except FRA version) 1.0 W (FRA version)	LOGIC	R3012
	2	• [HI/LOW] switch : LOW			500 mW (except FRA version) 150 mW (FRA version)		R3014
FM DEVIATION	1	 Operating channel : 16 Apply an AF signal to the [MIC] jack.: 1 kHz/150 mV Set the FM deviation meter. HPF : OFF LPF : 20 kHz De-emphasis: OFF Detector : (P-P)/2 Transmitting 	Top panel	Connect the FM deviation meter to the antenna connector via the attenuator.	±4.5 kHz	MIC	R1511
	2	 Apply an AF signal to the [MIC] jack.: 1 kHz/15 mV 			±3.0 kHz		R1514

MIC UNIT

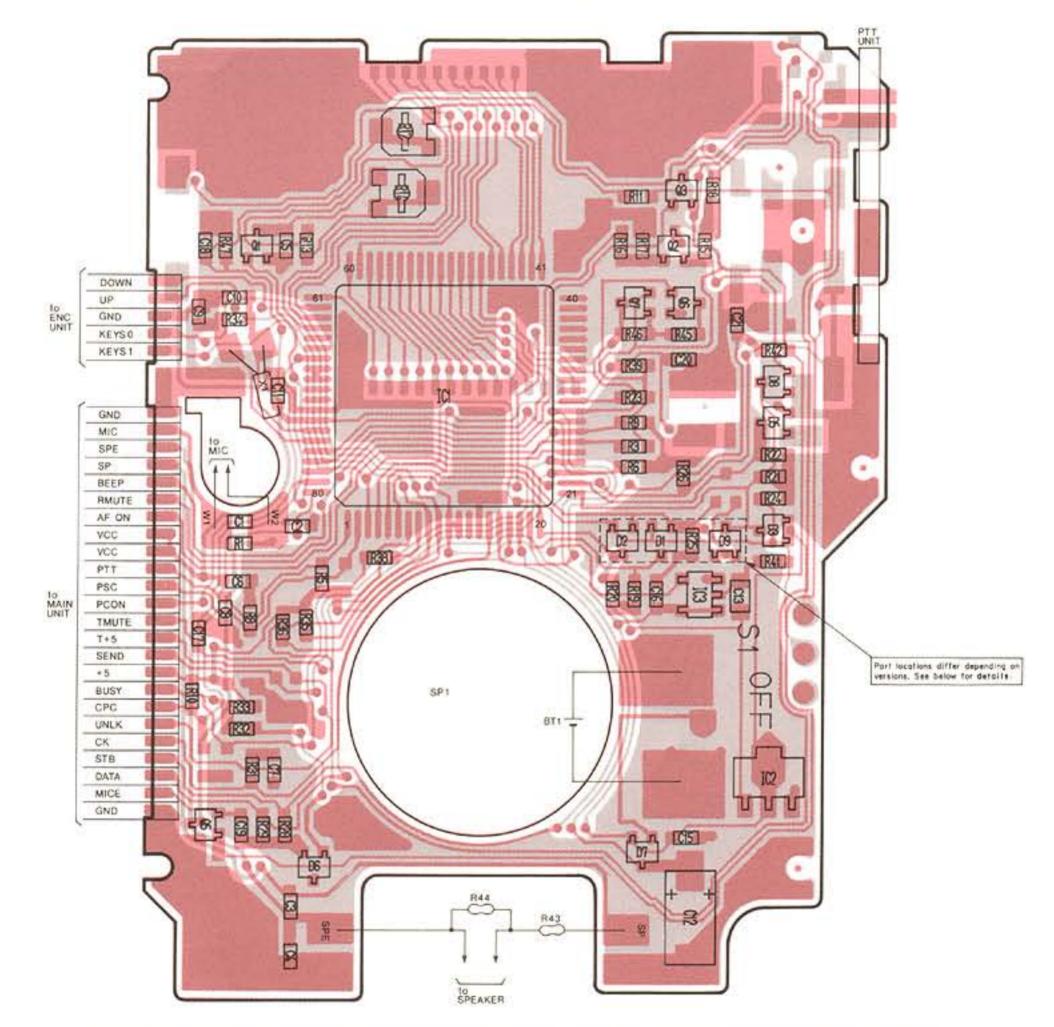


SECTION 8 BOARD LAYOUTS

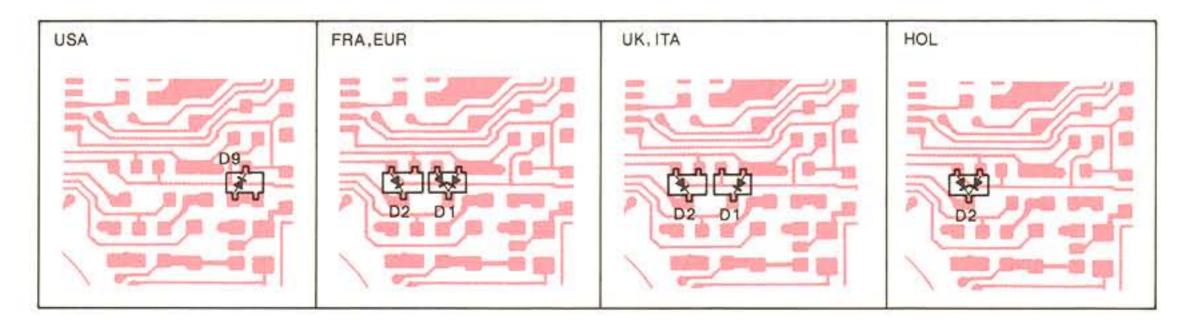
8-1 LOGIC UNIT

. LOGIC UNIT (TOP VIEW)

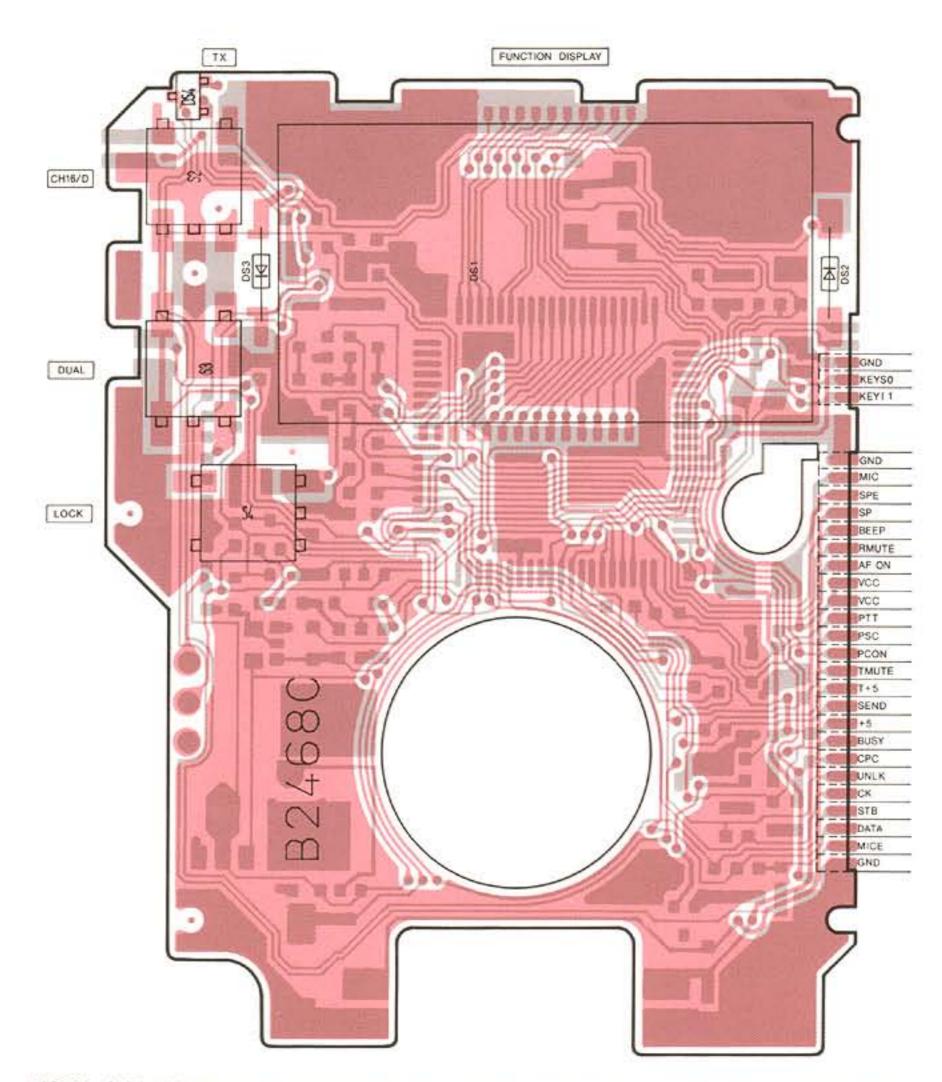
The combination of this page and the next page shows the unit layout in the same configuration as the actual P.C. Board.



NOTE: Add "3000" to each indicated part number on the unit for the actual part number.



 LOGIC UNIT (BOTTOM VIEW)



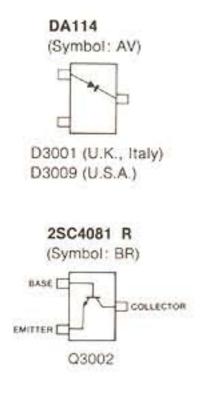
NOTE: Add "3000" to each indicated part number on the unit for the actual part number.

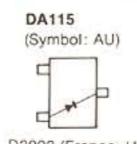
DA204U

C

(Symbol: K)

D3006

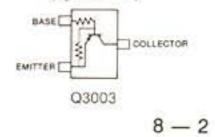


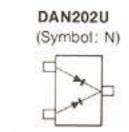


D3002 (France, U.K., Europe, Italy) D3003, D3005









D3001 (France, Europe) D3002 (Holland) D3007, D3008

DTC144EU

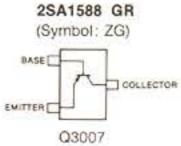
(Symbol: 26)

Q3001, Q3005, Q3006

COLLECTOR

BASE WAY

EMITTER



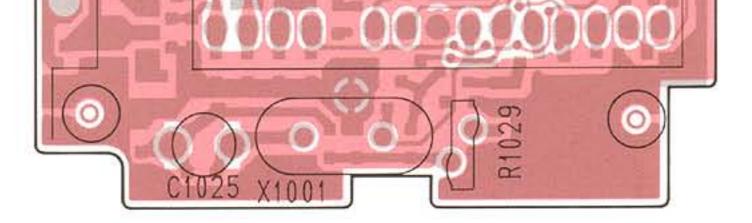


8-2 MAIN UNIT

• MAIN UNIT (TOP VIEW)

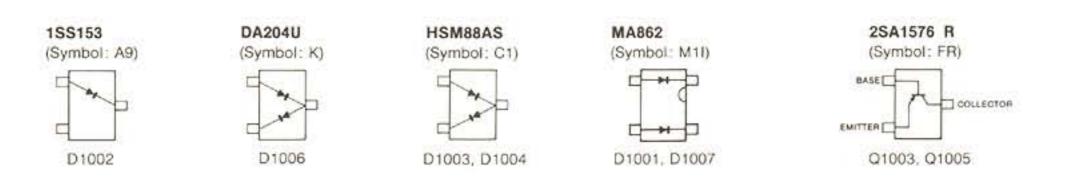
P.C. Board. 10 VR UNIT SP MIC P1001 CHARGE ANT OND SOL REG UNIT d we 7301 园 650‡ [330] END EBB 0.02 1001 003 CBN. 0 14 [[]] 3 0 3 AF UNIT 1003 W1002 Ð 006 100 L1010 C104 α 00 á 1NP RE-UNIT 0 1 DETA UNIT L ICI 1005 046 ٠

The combination of this page and the next page shows the unit layout in the same configuration as the actual P.C. Board.

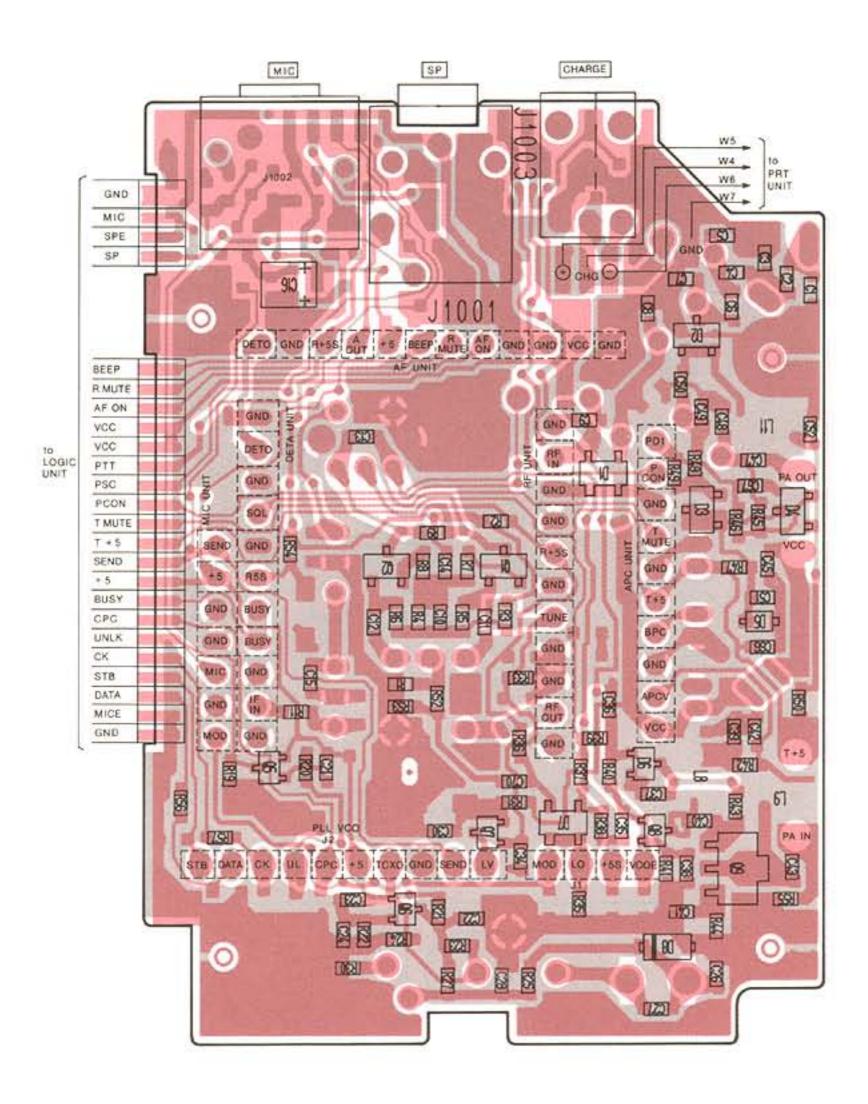


PLL VCO UNIT

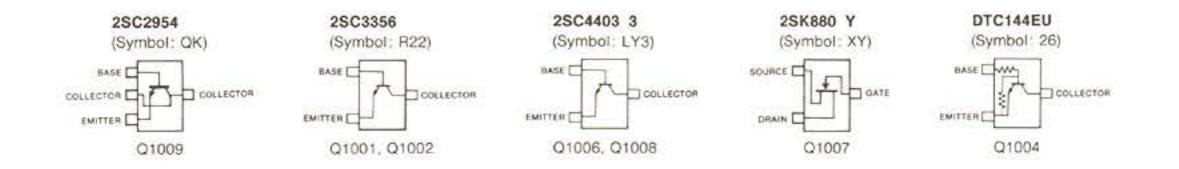
NOTE: Add "1000" to each indicated part number on the unit for the actual part number.



MAIN UNIT (BOTTOM VIEW)

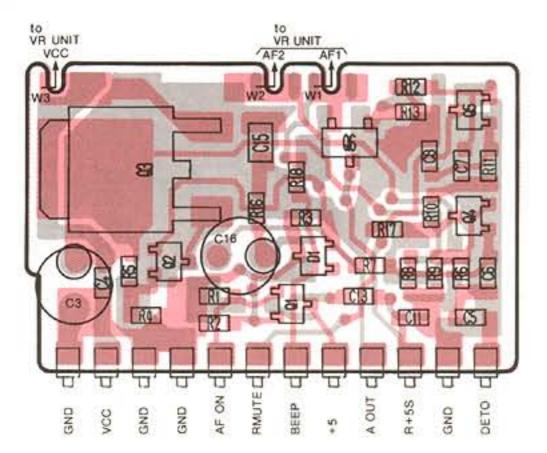


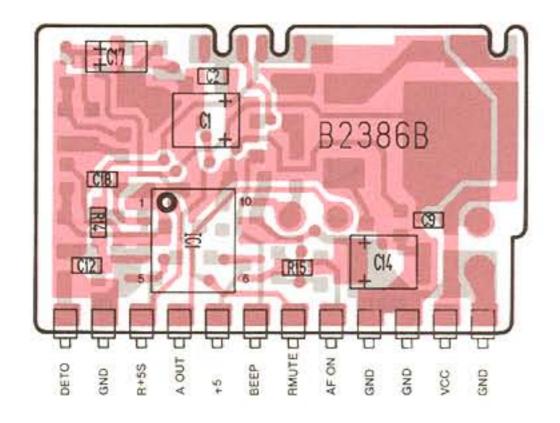
NOTE: Add "1000" to each indicated part number on the unit for the actual part number.



8-3 AF AND MIC UNITS

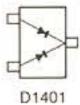
AF UNIT





DAN202U

(Symbol: N)



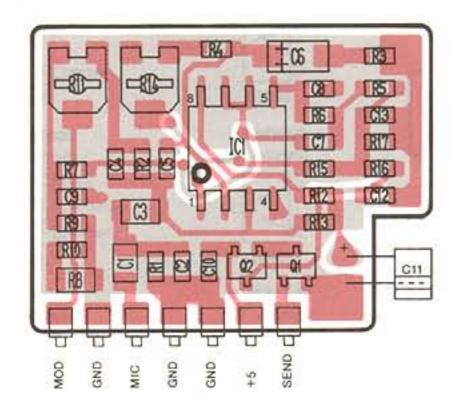
2SB1182F5 Q

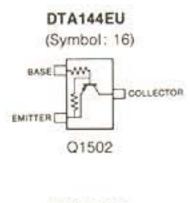
2SC4081 R (Symbol: BR) BASE COLLECTOR EMITTER Q1401, Q1402, Q1404 Q1405

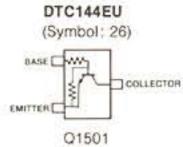
2SJ106 GR (Symbol: VG) SOURCE GATE DRAIN OI 406

NOTE: Add "1400" to each indicated part number on the unit for the actual part number.







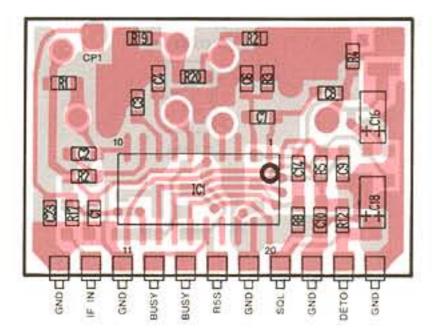


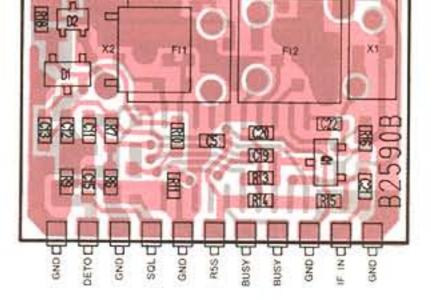
NOTE: Add "1500" to each indicated part number on the unit for the actual part number.

8-5

8-4 DETA, APC AND REG UNITS

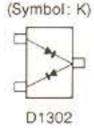
DETA UNIT

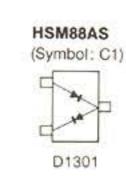


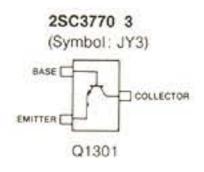


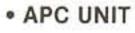
NOTE: Add "1300" to each indicated part number on the unit for the actual part number.

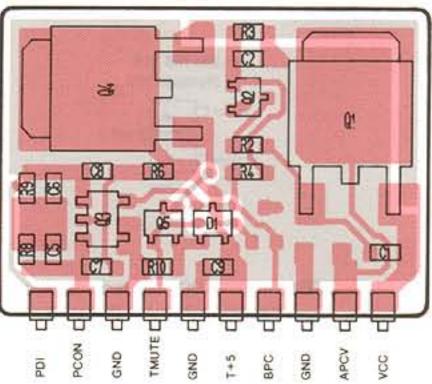
DA204U

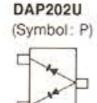




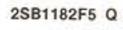




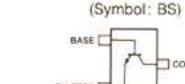


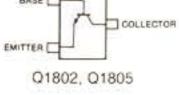




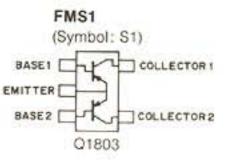




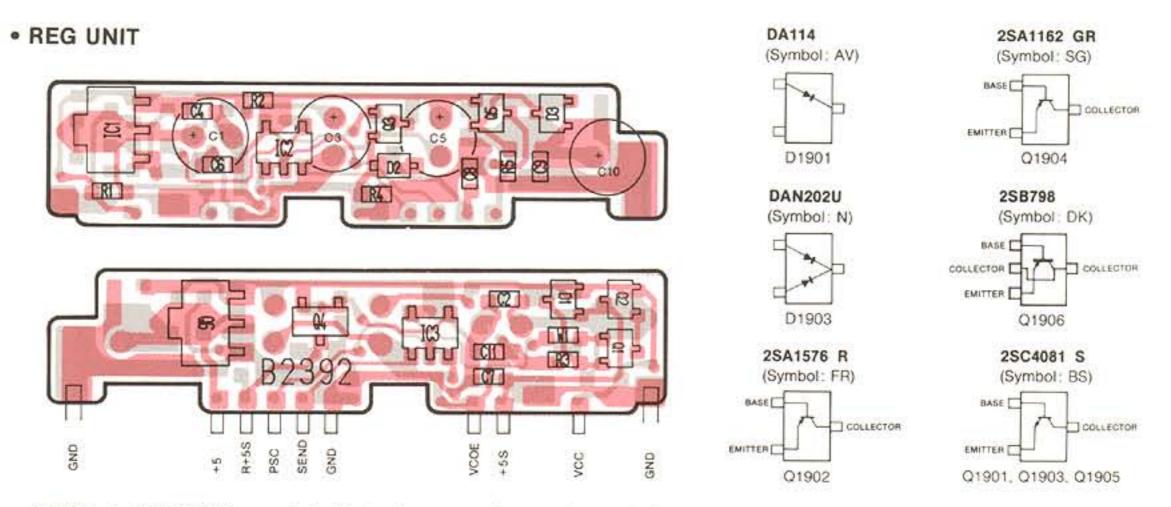




2SC4081 S



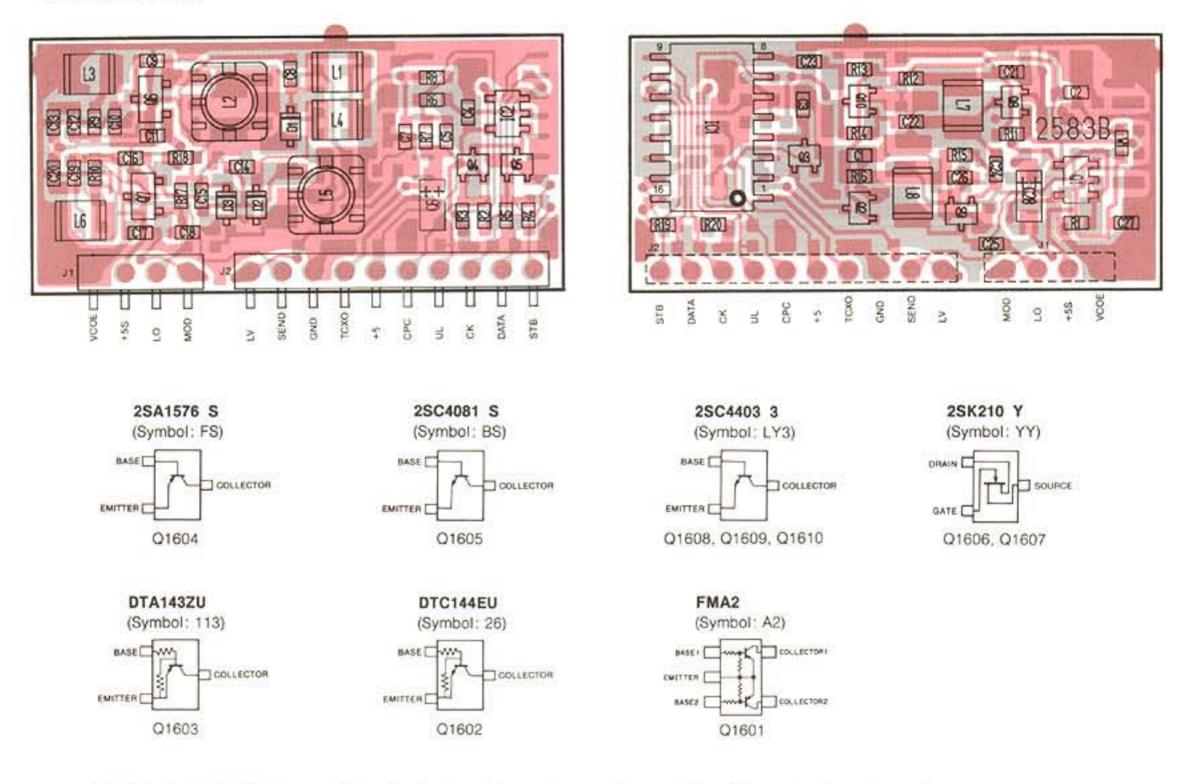
NOTE: Add "1800" to each indicated part number on the unit for the actual part number.



NOTE: Add "1900" to each indicated part number on the unit for the actual part number.

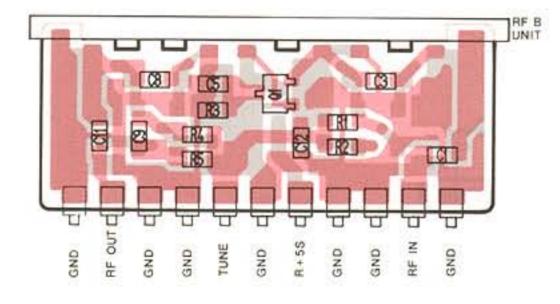
8-5 PLL VCO, RFA AND RFB UNITS

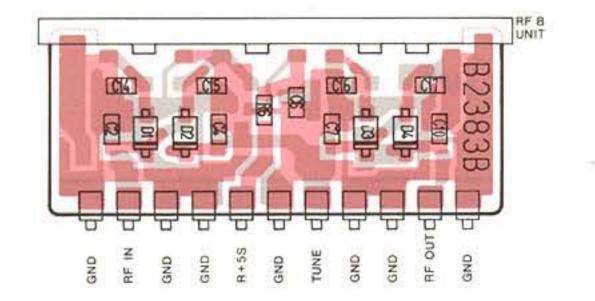
PLL VCO UNIT



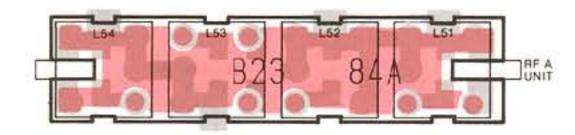
NOTE: Add "1600" to each indicated part number on the unit for the actual part number.

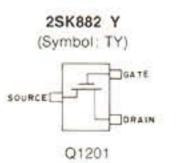
RFA UNIT





RFB UNIT

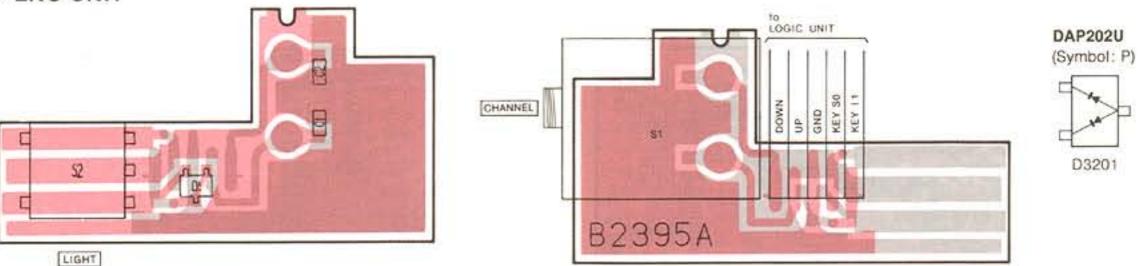




NOTE: Add "1200" to each indicated part number on the unit for the actual part number.

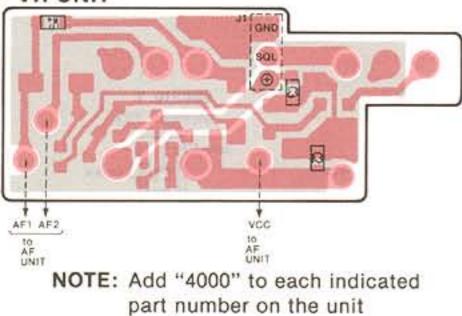
8-6 LOGIC AND PRT UNITS

ENC UNIT

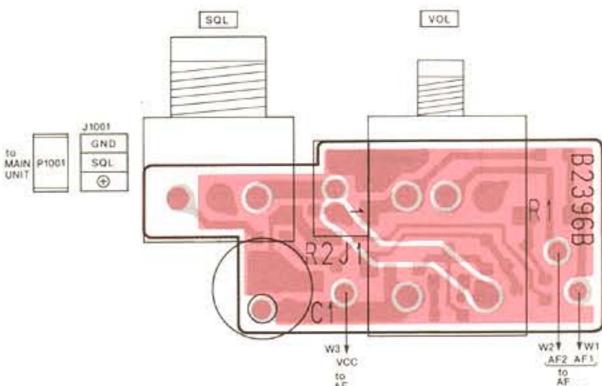


NOTE: Add "3200" to each indicated part number on the unit for the actual part number.

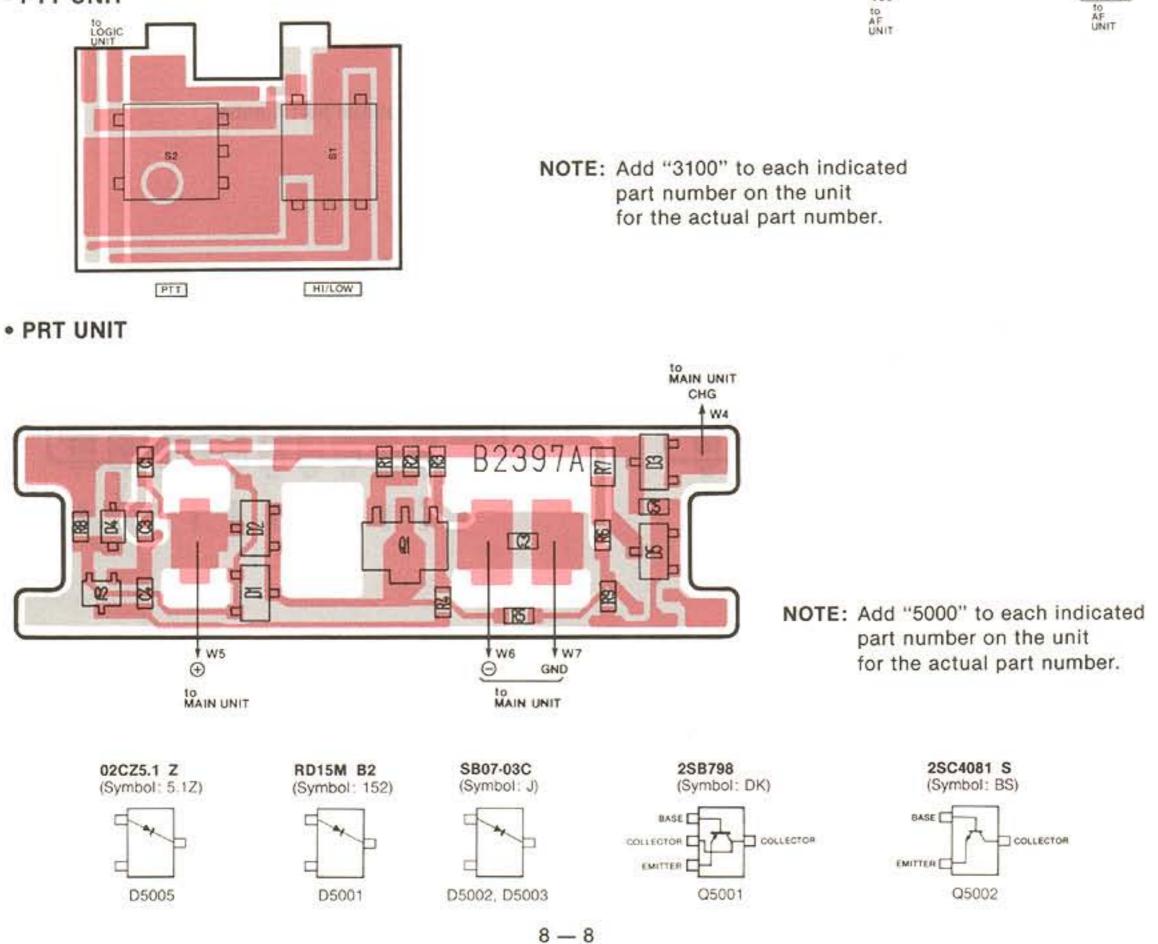
VR UNIT



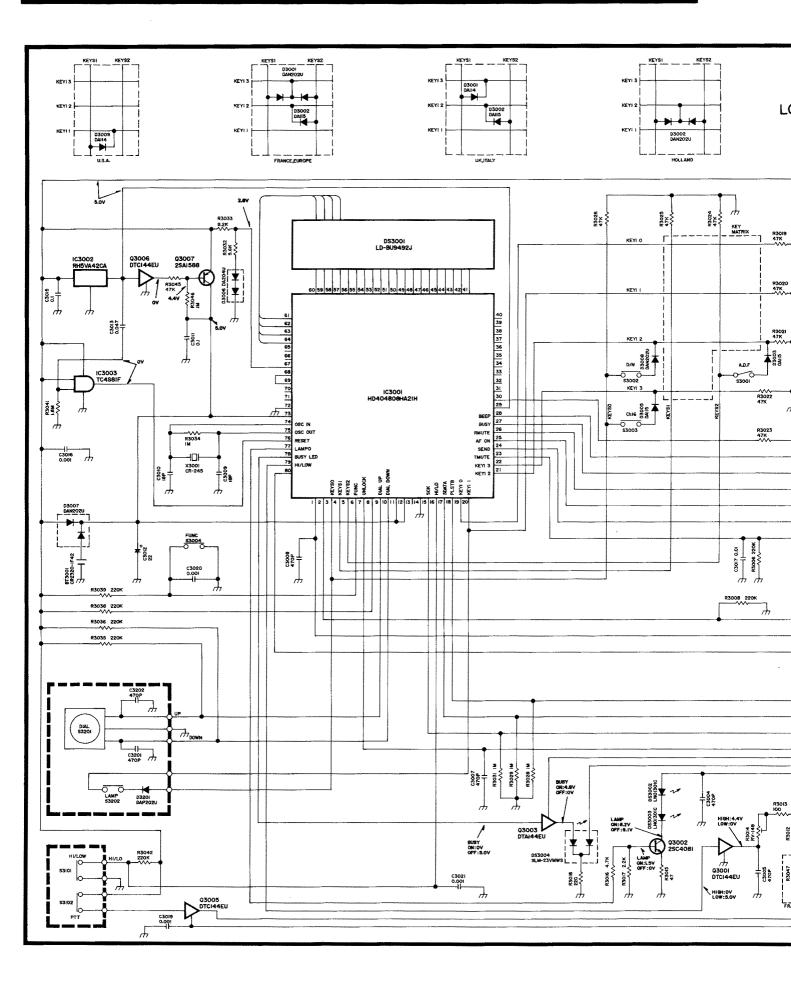
for the actual part number.

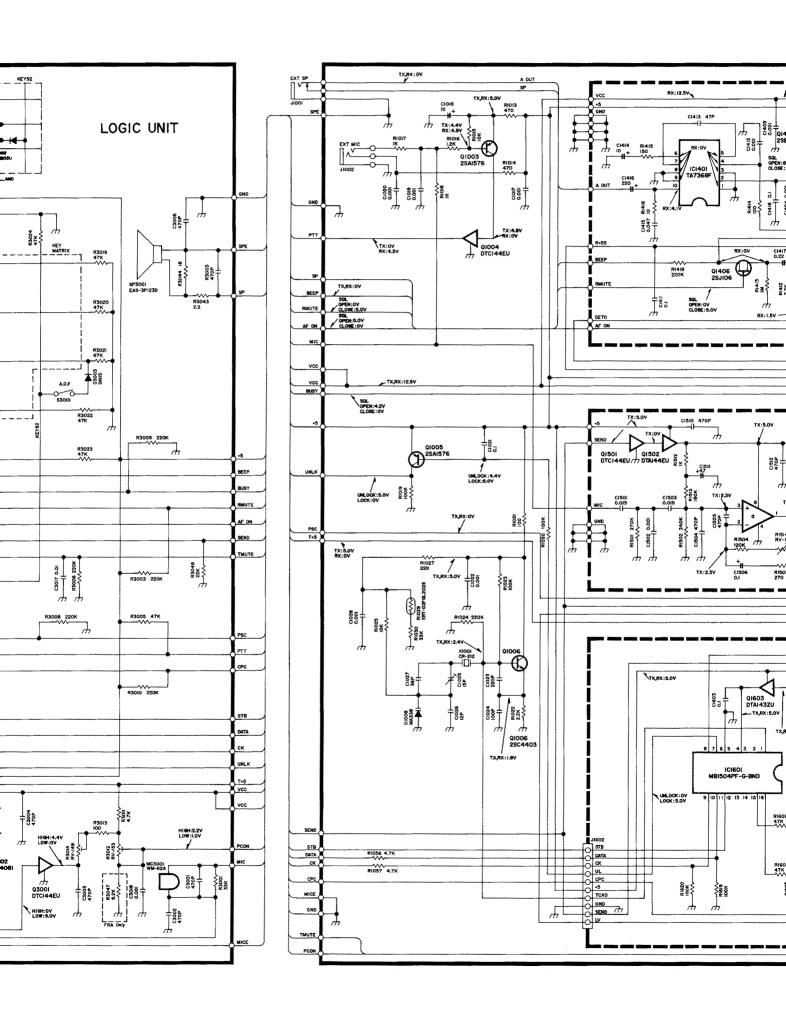


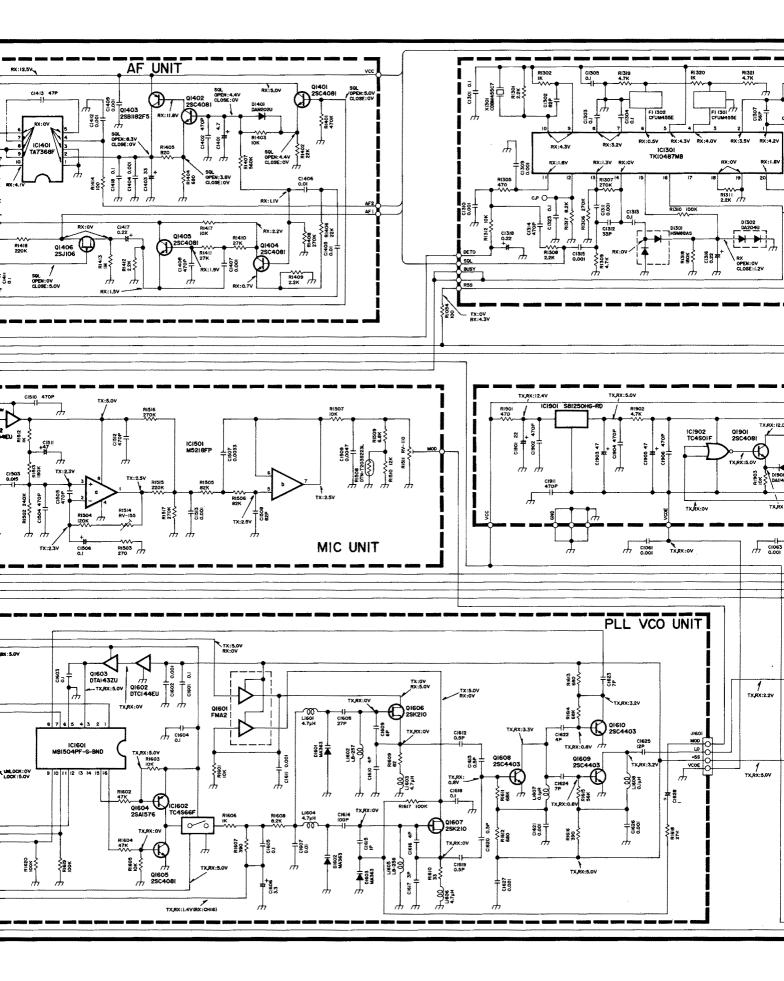


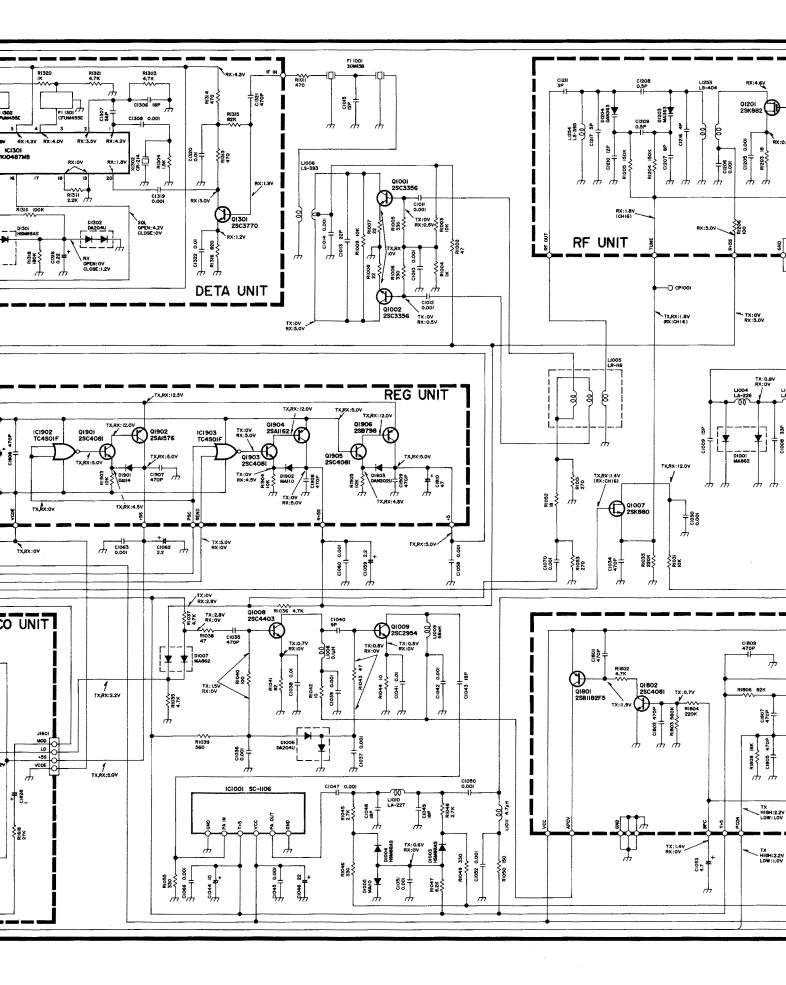


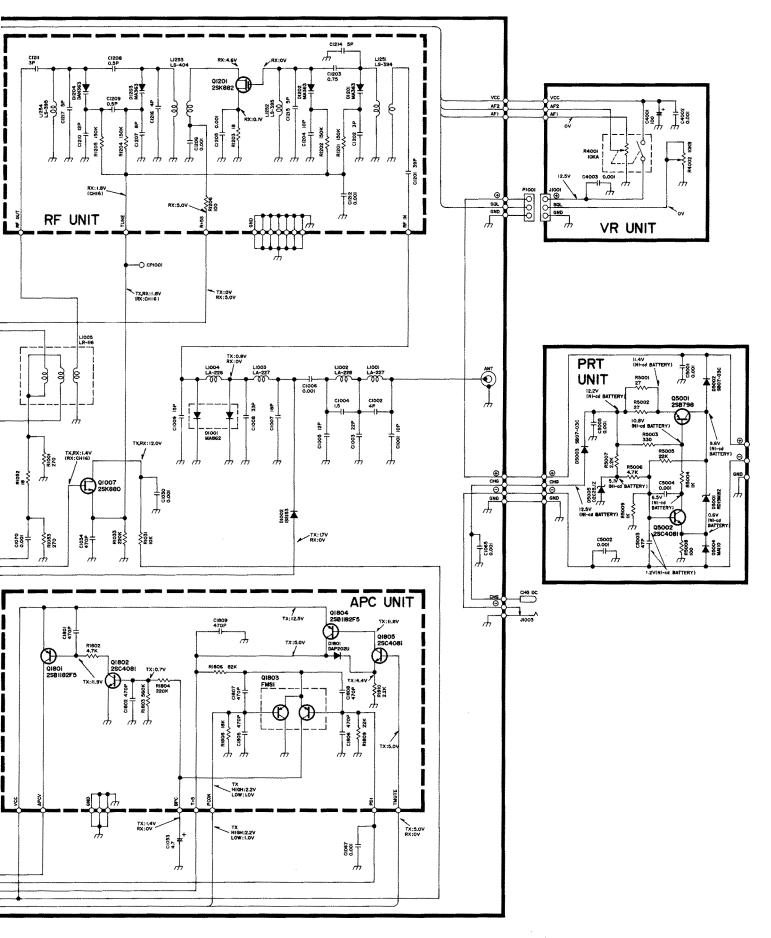
SECTION 9 VOLTAGE DIAGRAM











9 — 1

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